



Scanning Probe Microscope: A powerful Tool for Imaging Nanoscale Charge Transport Properties

Never Stand Still

Faculty of Engineering

School of Photovoltaic and Renewable Energy Engineering

Jae Sung Yun

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Advanced Photovoltaics Fellow
UNSW, Australia***

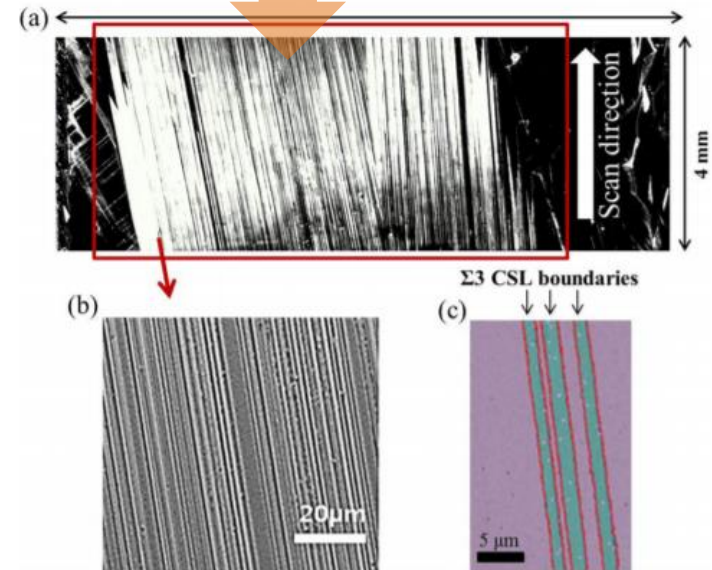
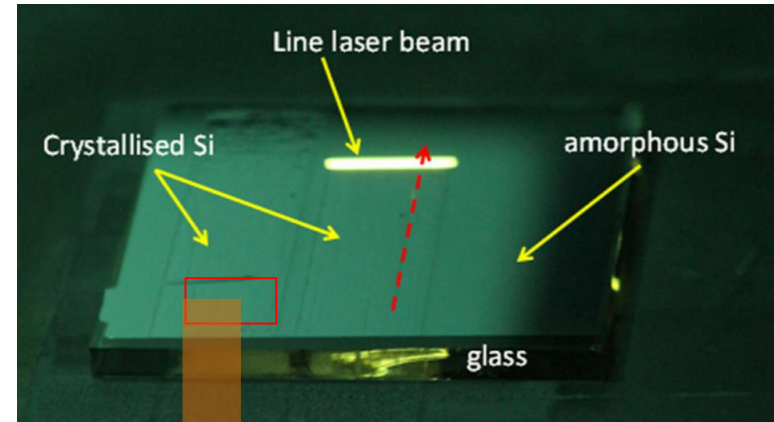
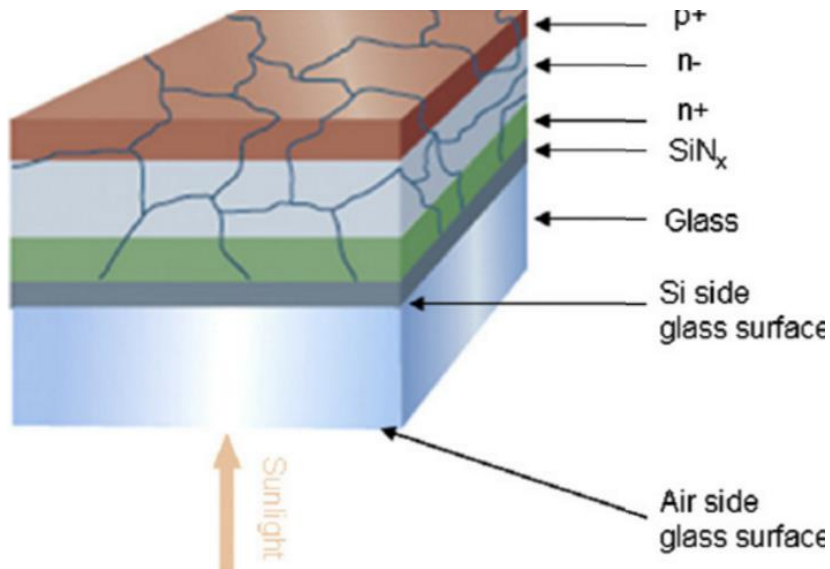


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MOTIVATION

Crystalline Si thin film on Glass (CSG) Technology



Any method to observe PV characteristics of structural defects in nanoscale? “Spatial resolution of few tenth of nanometre is required”

J. Yun, et al. Appl. Phys. Lett. 2014

ATOMIC FORCE MICROSCOPY

VOLUME 56, NUMBER 9

PHYSICAL REVIEW LETTERS

3 MARCH 1986

Atomic Force Microscope

G. Binnig^(a) and C. F. Quate^(b)

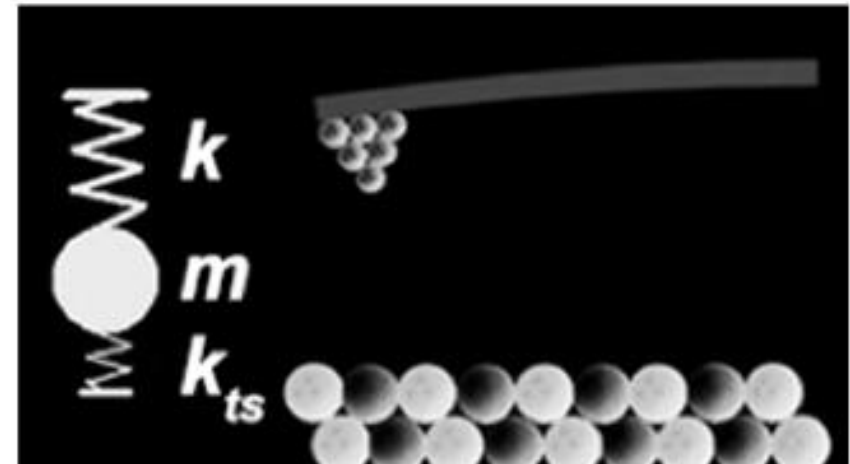
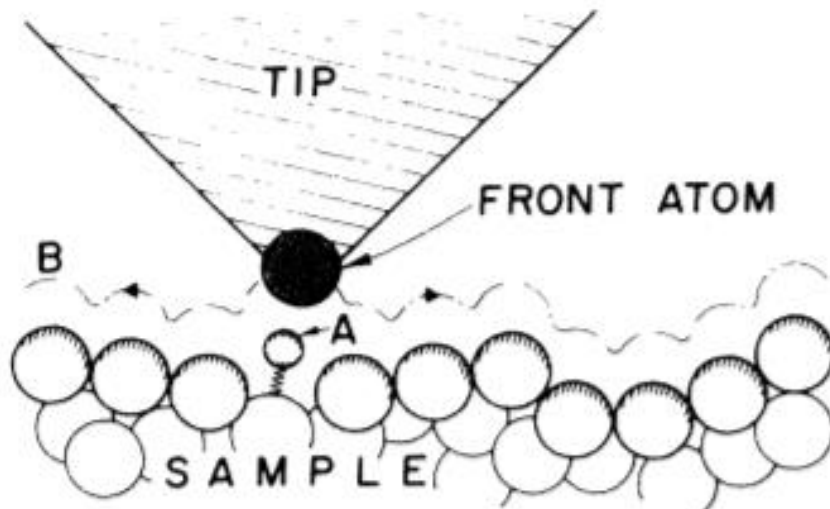
Edward L. Ginzton Laboratory, Stanford University, Stanford, California 94305

and

Ch. Gerber^(c)

IBM San Jose Research Laboratory, San Jose, California 95193

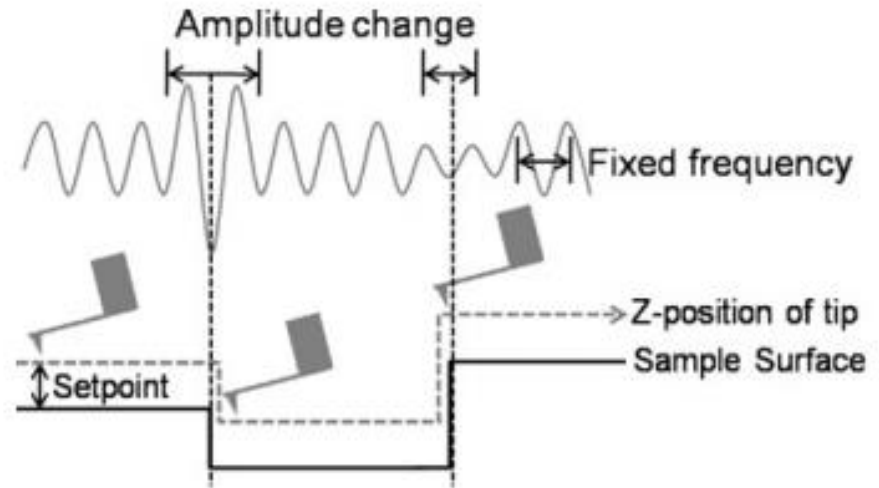
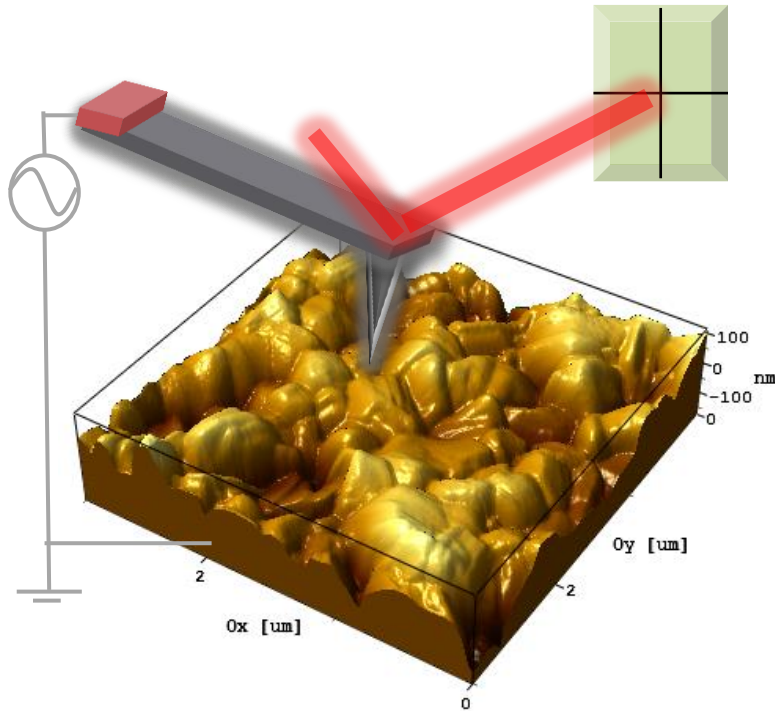
(Received 5 December 1985)



F. Giessibl, *Rev. Mod. Phys.* **75**, 949 (2003)

“Atomic interaction between tip and the sample”

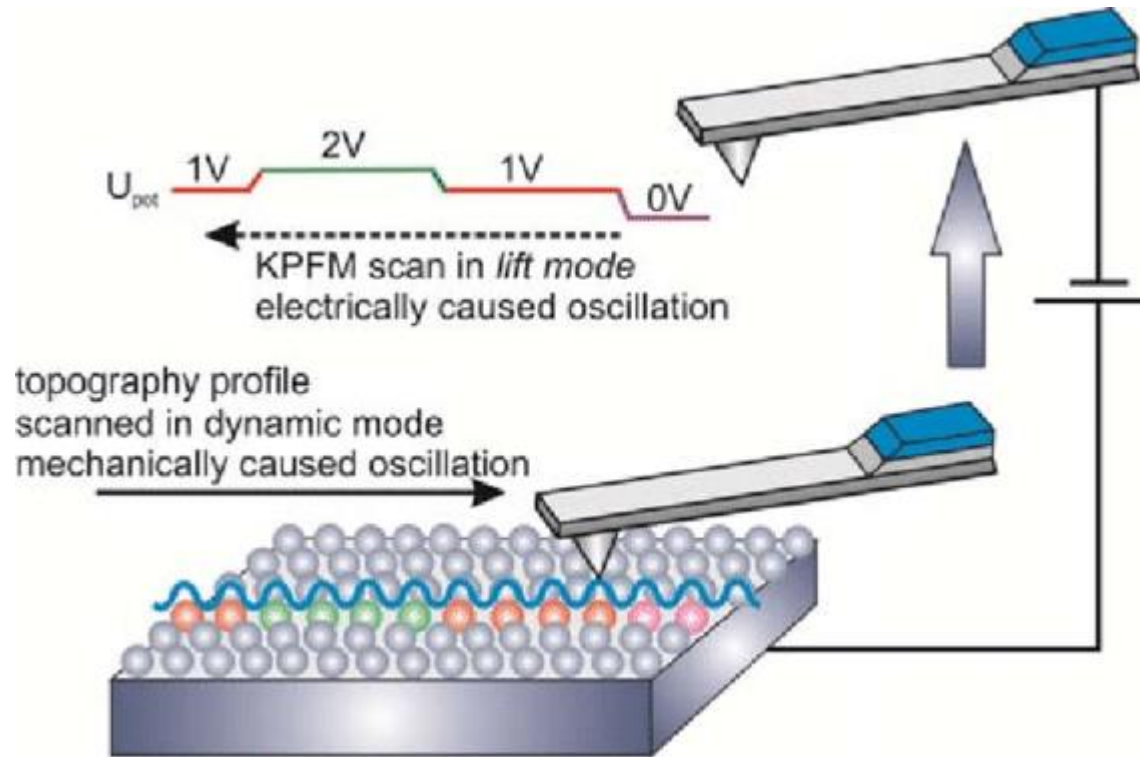
NON-CONTACT MODE AFM



1. Vibration at slightly above the resonance frequency of probe.
2. Rise to shift of the resonance frequency due to the interaction.
3. The changes in the oscillation amplitude are monitored and the feedback signals keeps constant the force gradient.

Surface Science Reports 66 (2011) 1–27

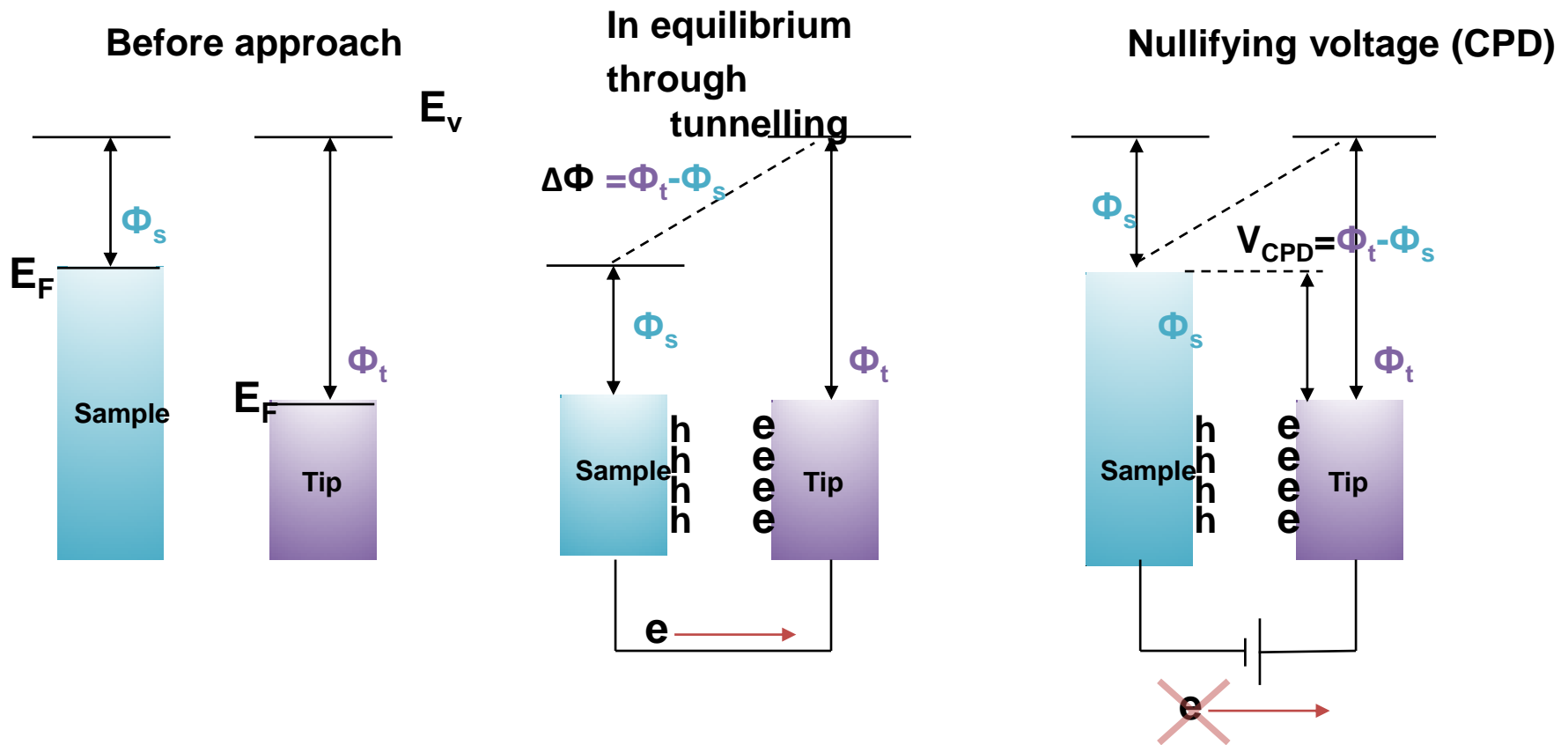
KELVIN PROBE FORCE MICROSCOPY



Przegląd Elektrotechniczny 91.9 (2015): 166-169.

1st pass → Height
2nd pass → CPD → **Imaging height signal and CPD signal at the same spot!**

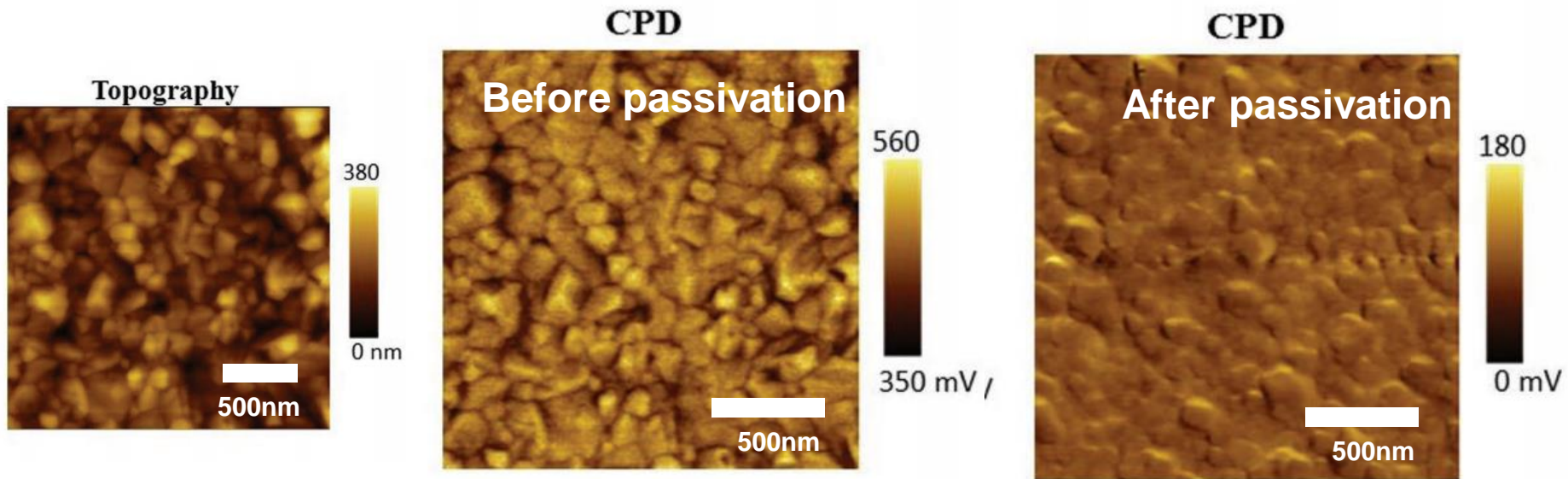
CONTACT POTENTIAL DIFFERENCE (CPD)



An **electrostatic force** exists between tip and sample due to work function difference and **DC voltage** is applied to **nullify** the force. >1 nm and >1 mV spatial resolution

CONTACT POTENTIAL DIFFERENCE (CPD)

CPD measures **work function of a sample surface**

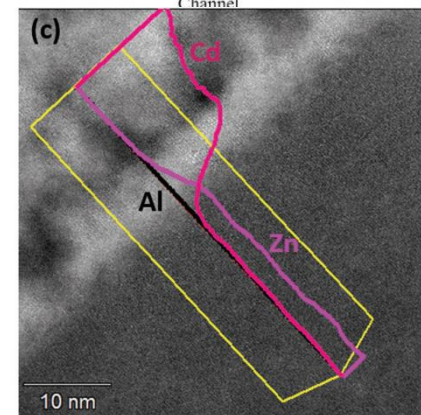
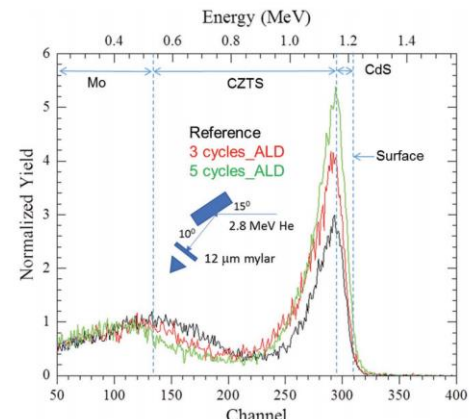
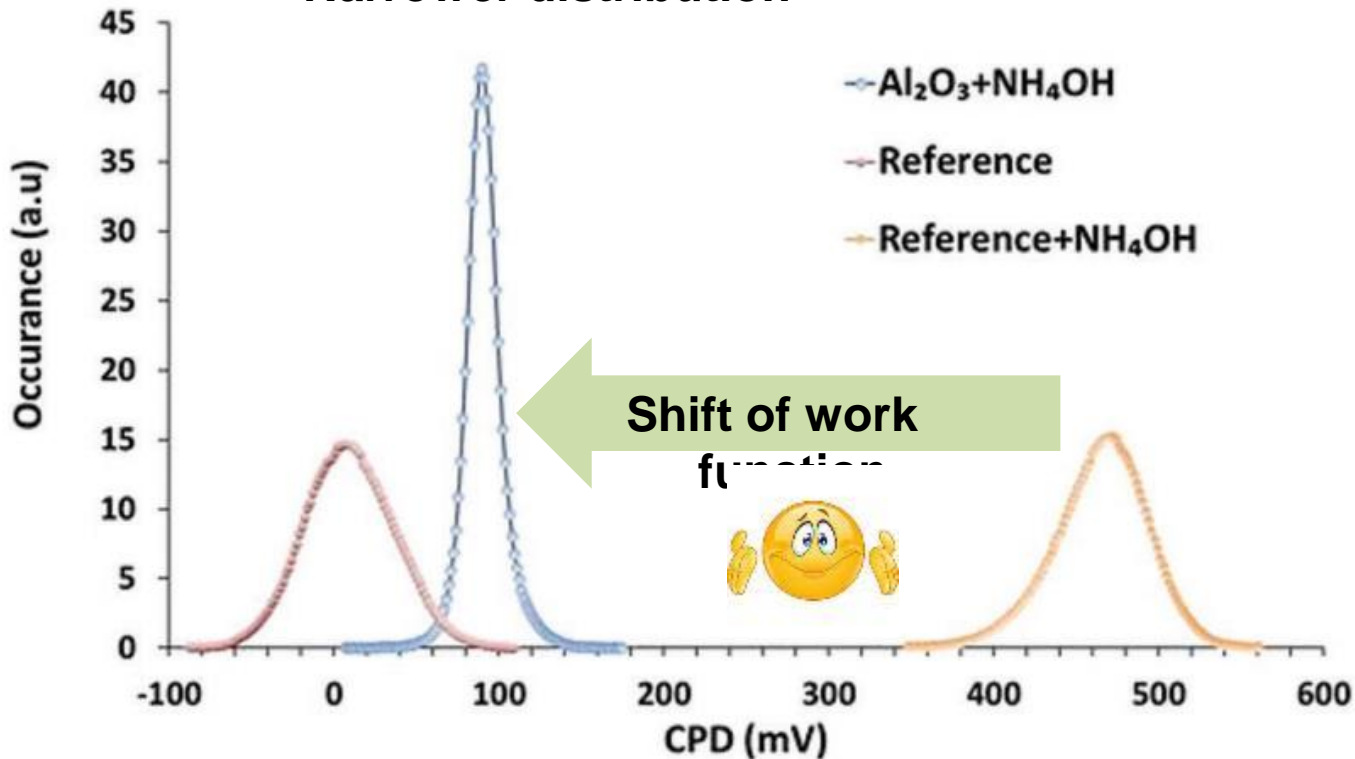


What does this mean to us?

Advanced Energy Materials 8 (23), 1701940

CONTACT POTENTIAL DIFFERENCE (CPD)

Narrower distribution



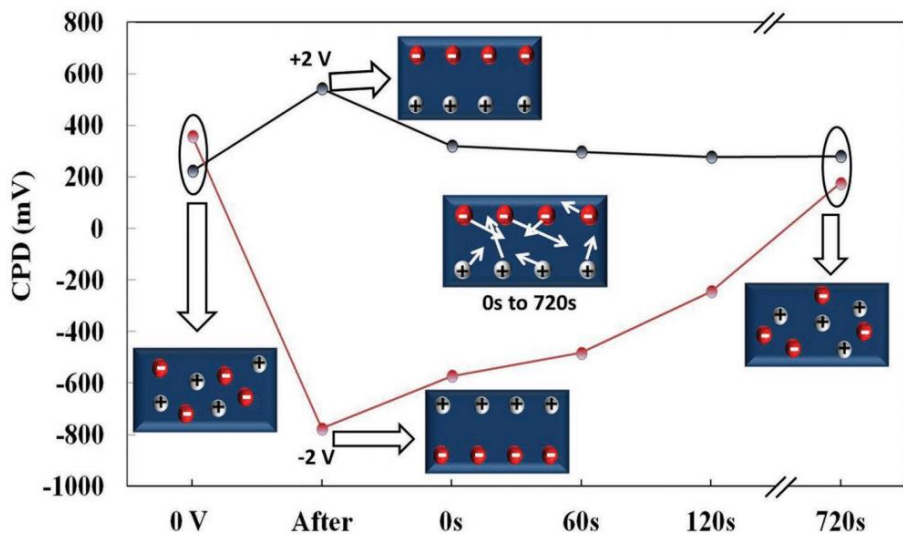
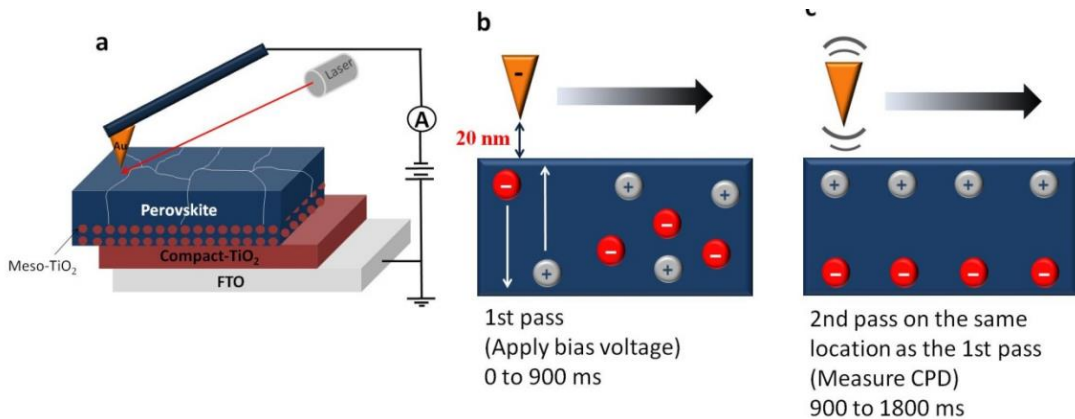
Advanced Energy Materials 8 (23), 1701940

What made a shift of work function?

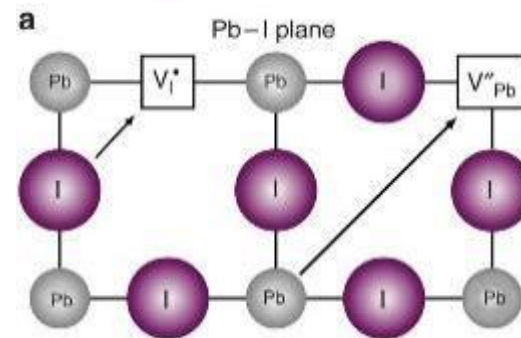
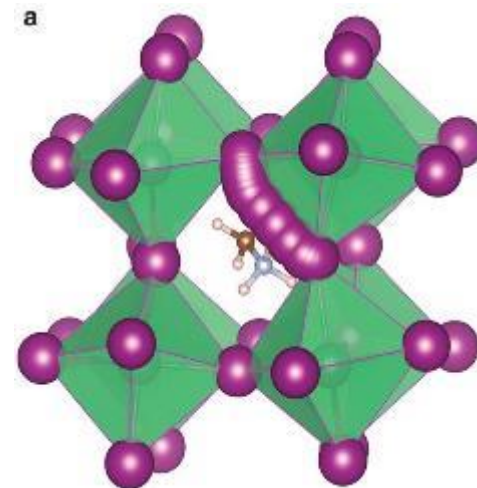
- Charge carrier density, bandgap, surface states, surface dipole, crystal orientation

It is always good to have results from other techniques such as SIMS, TEM, XRD, etc.

CONTACT POTENTIAL DIFFERENCE (CPD)



J. Yun et al. *Advanced Energy Materials* 6 (13), 1600330

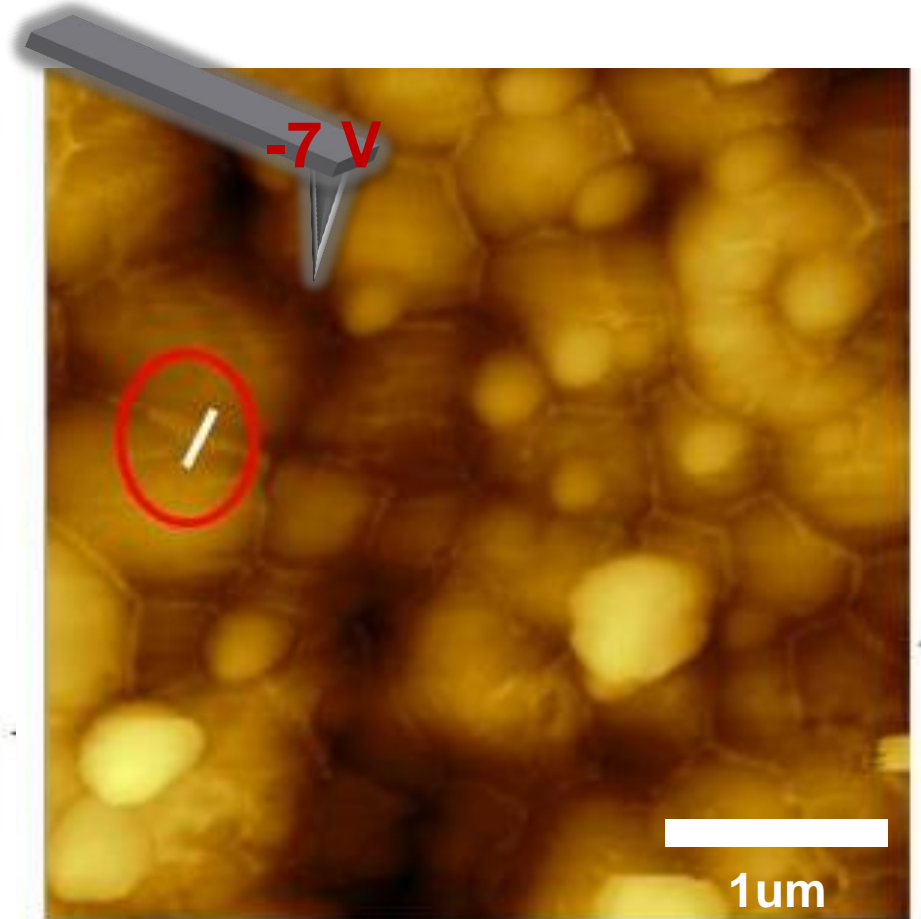
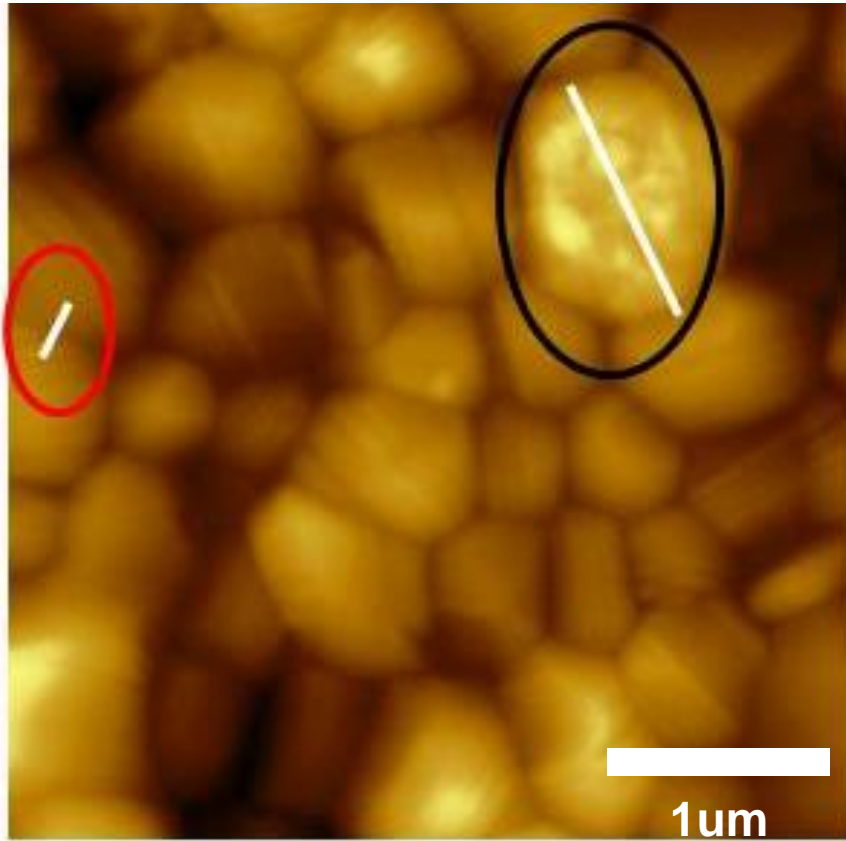


Nature Communications 6, 7497 (2015)

Iodide vacancies in halide perovskite changes work function

ION MIGRATION IN HALIDE PEROVSKITE

0 V

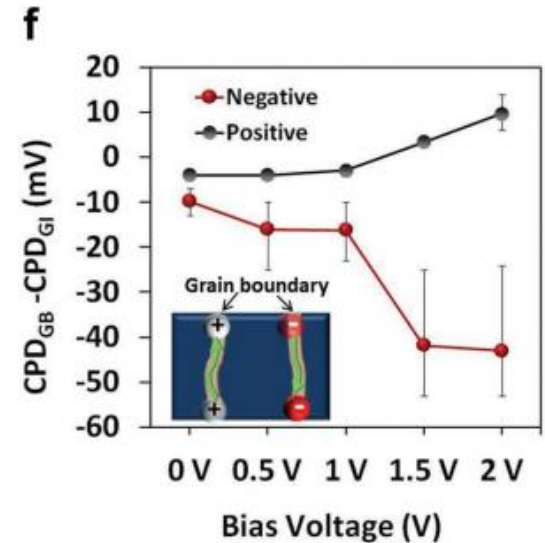
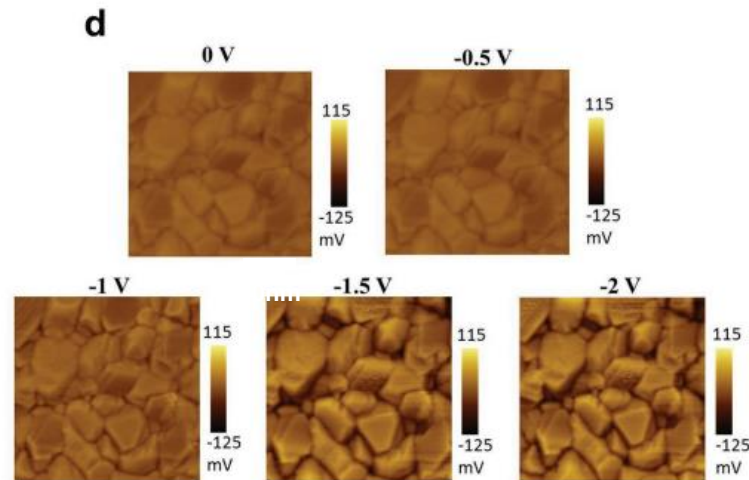
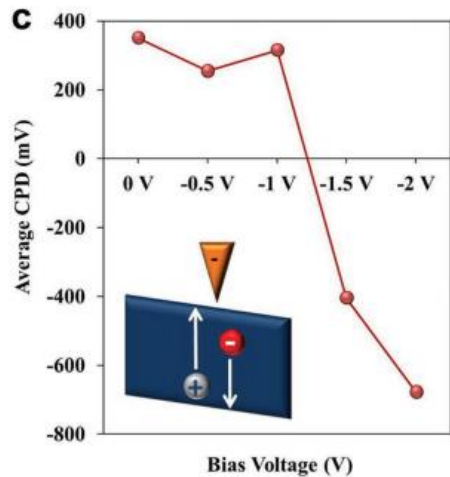
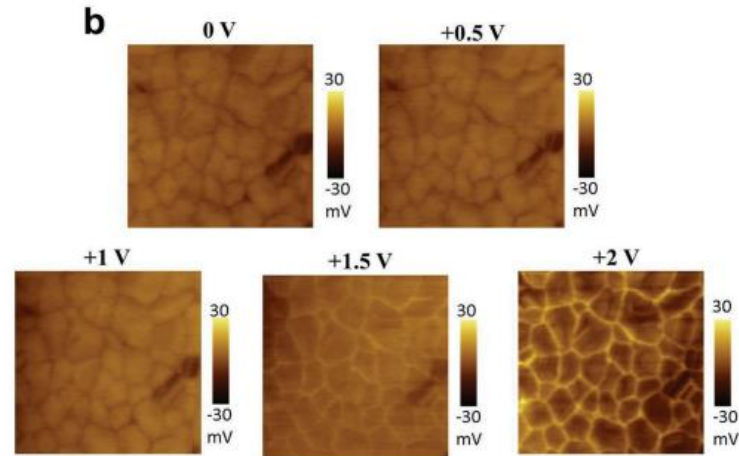
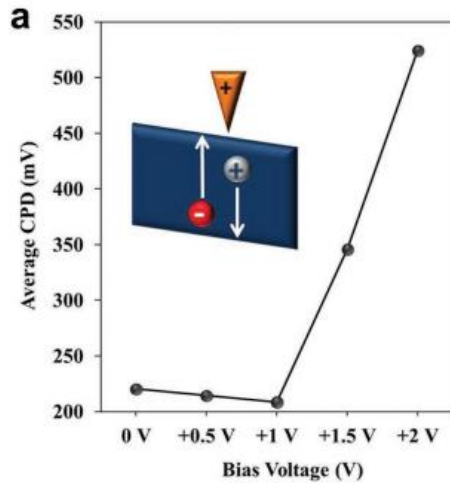


J. Yun et al. Advanced Energy Materials 6 (13), 1600330

4x4 μm

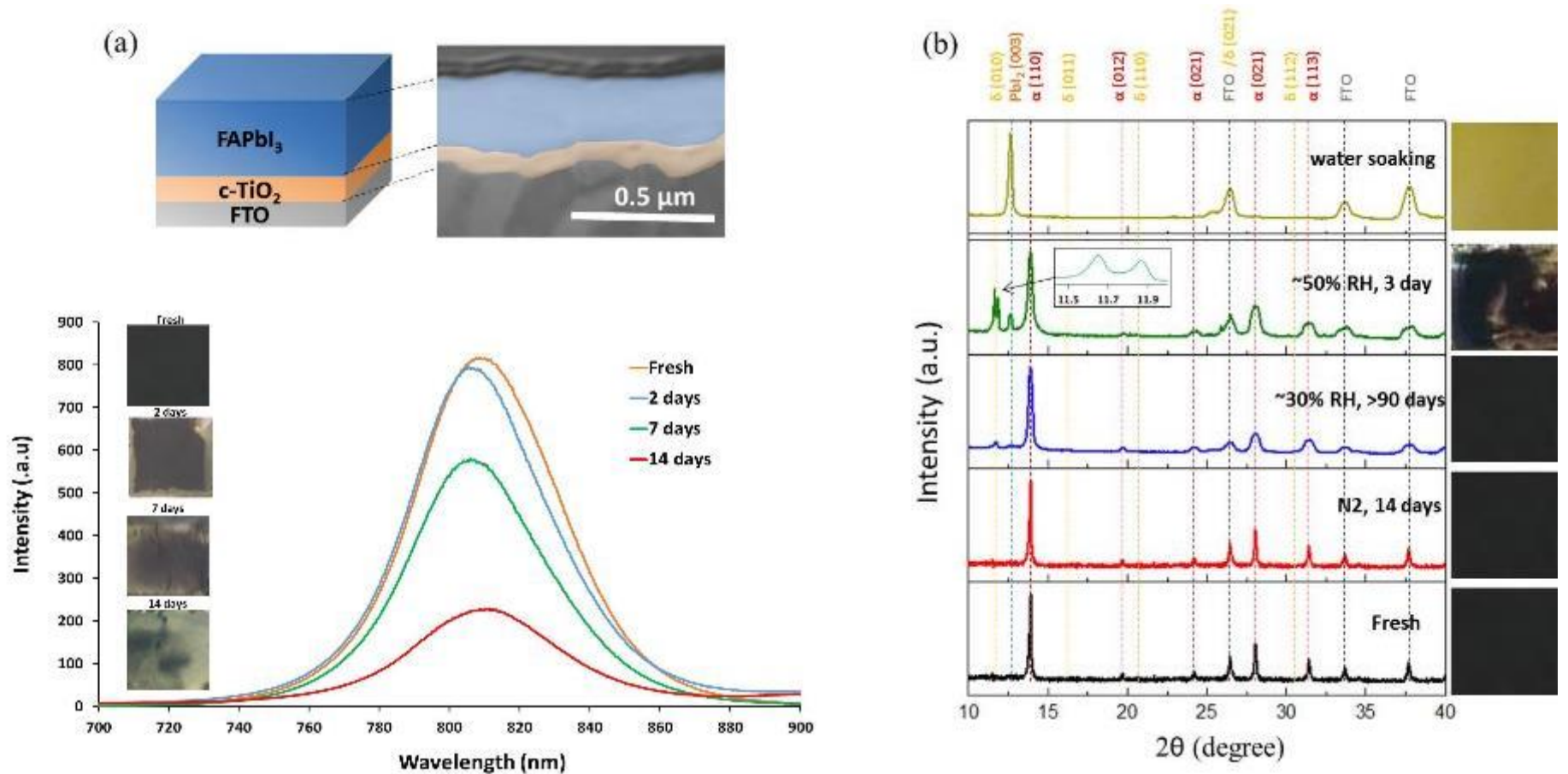
Grain boundaries are inflated due to the ion migration

ION MIGRATION IN HALIDE PEROVSKITE



Grain boundaries act as channels for ion migration

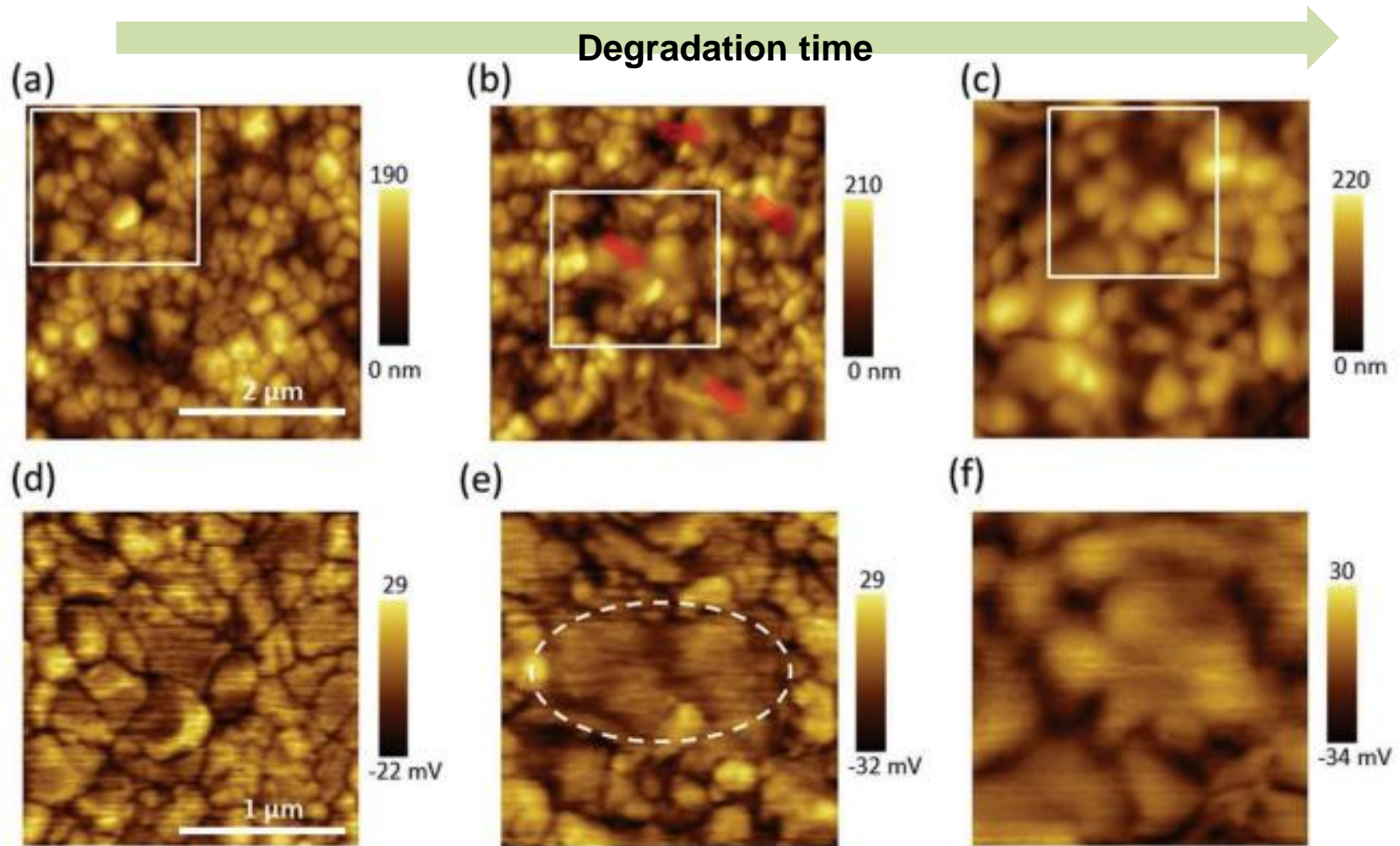
DEGRADATION IN HALIDE PEROVSKITE



J. Yun et al. Advanced Functional Materials 28 (3), 1705363

FAPbI₃ Perovskite turn into non-perovskite phase at room temperature

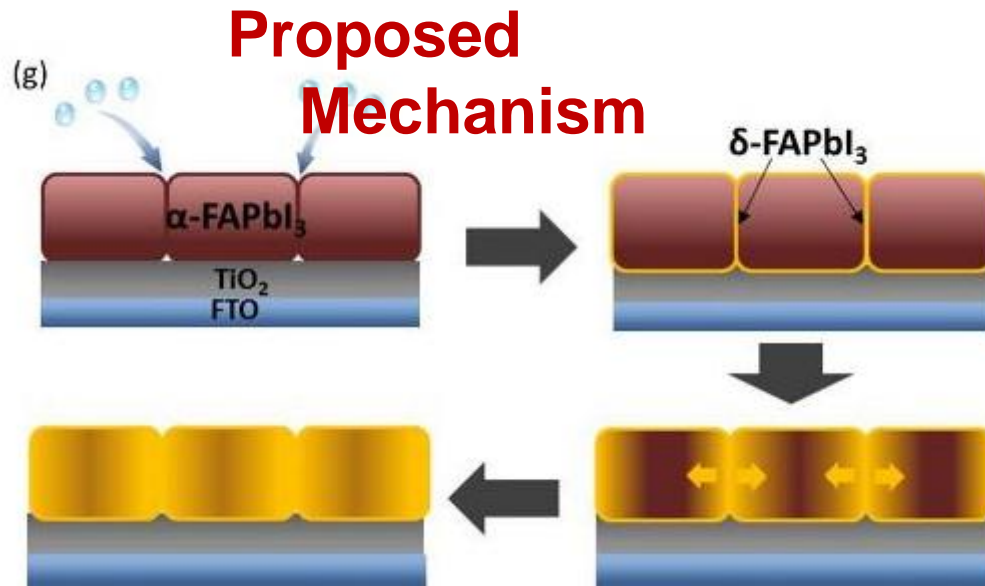
DEGRADATION IN HALIDE PEROVSKITE



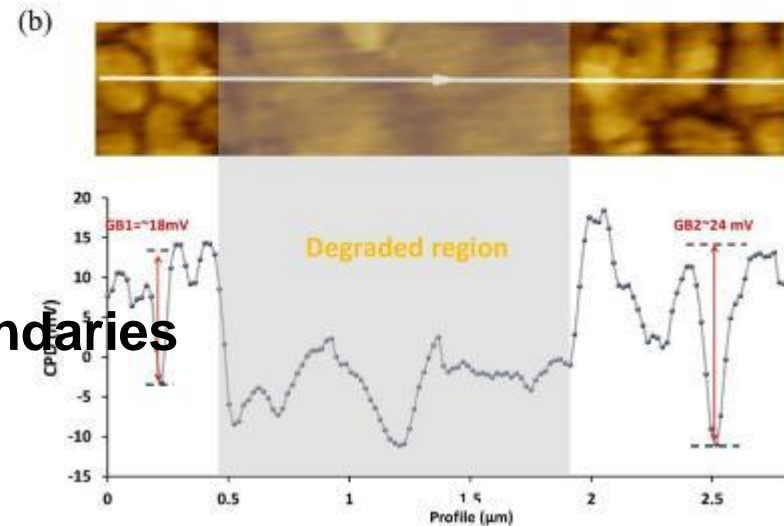
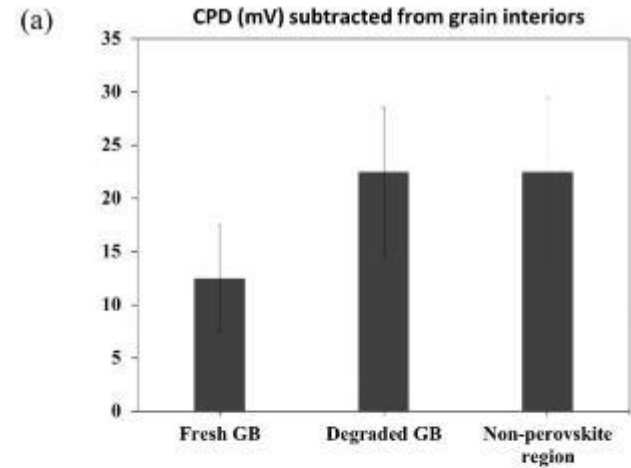
J. Yun et al. *Advanced Functional Materials* 28 (3), 1705363

Grains merge and grain boundaries become wide and lower CPD

DEGRADATION IN HALIDE PEROVSKITE

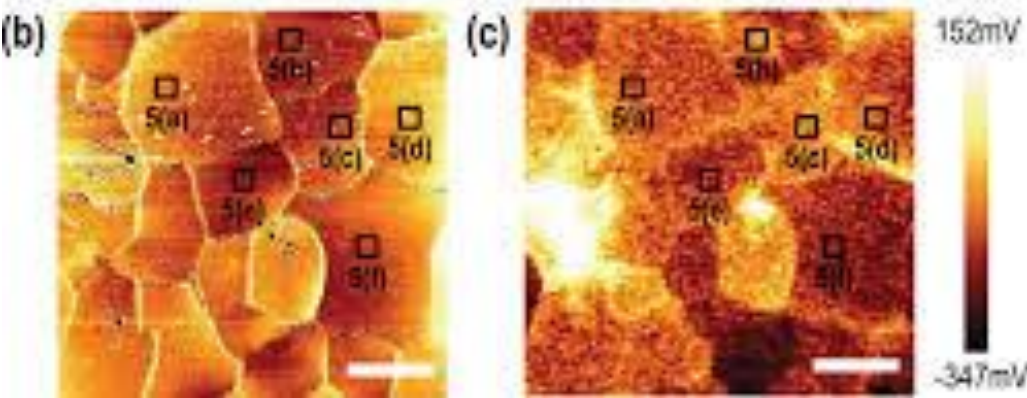
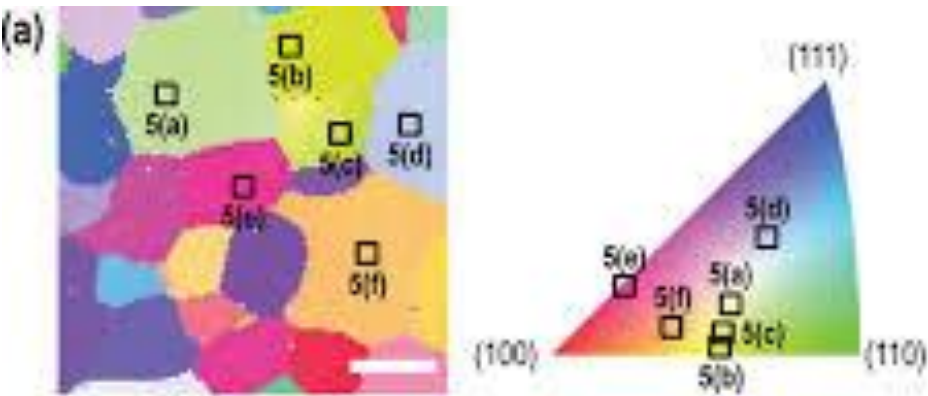


Moisture penetrate through the grain boundaries and yellow phase spreads laterally

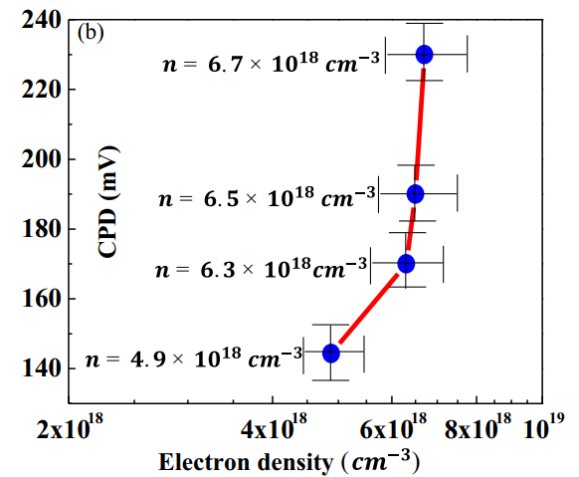
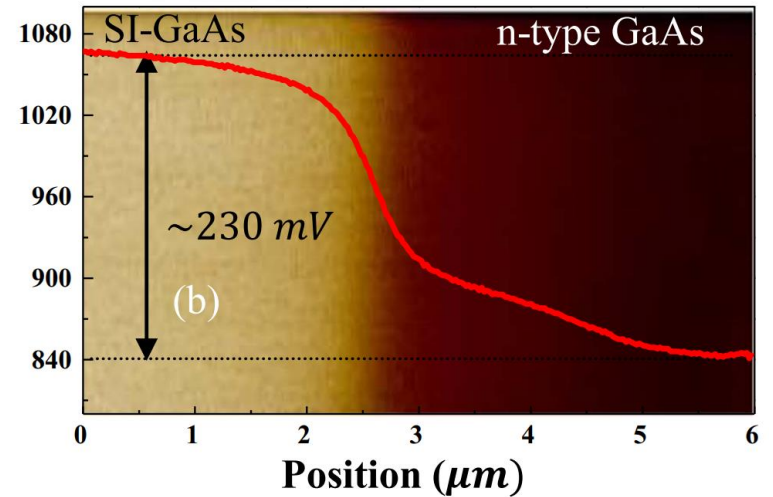


J. Yun et al. Advanced Functional Materials 28 (3), 1705363

OTHER APPLICATIONS



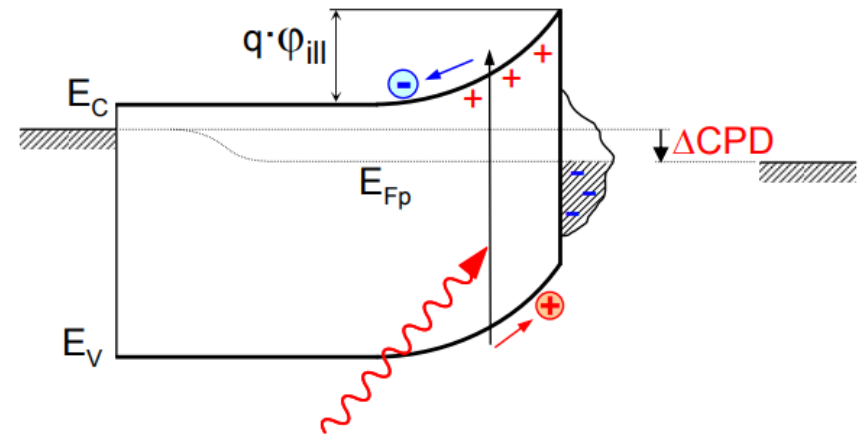
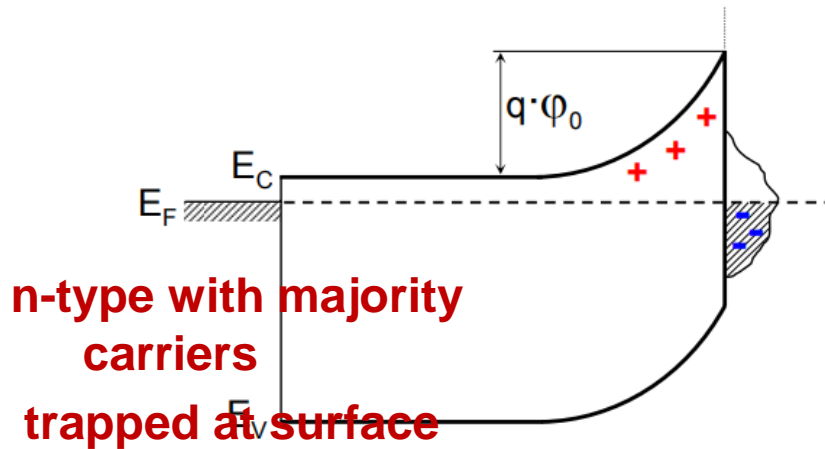
Scientific reports 5 (2015): 8822



Philosophical magazine letters 85.1 (2005): 41-49.

SURFACE PHOTOVOLTAGE

$$\text{Surface photovoltage} = \text{CPD}_{\text{light}} - \text{CPD}_{\text{dark}}$$



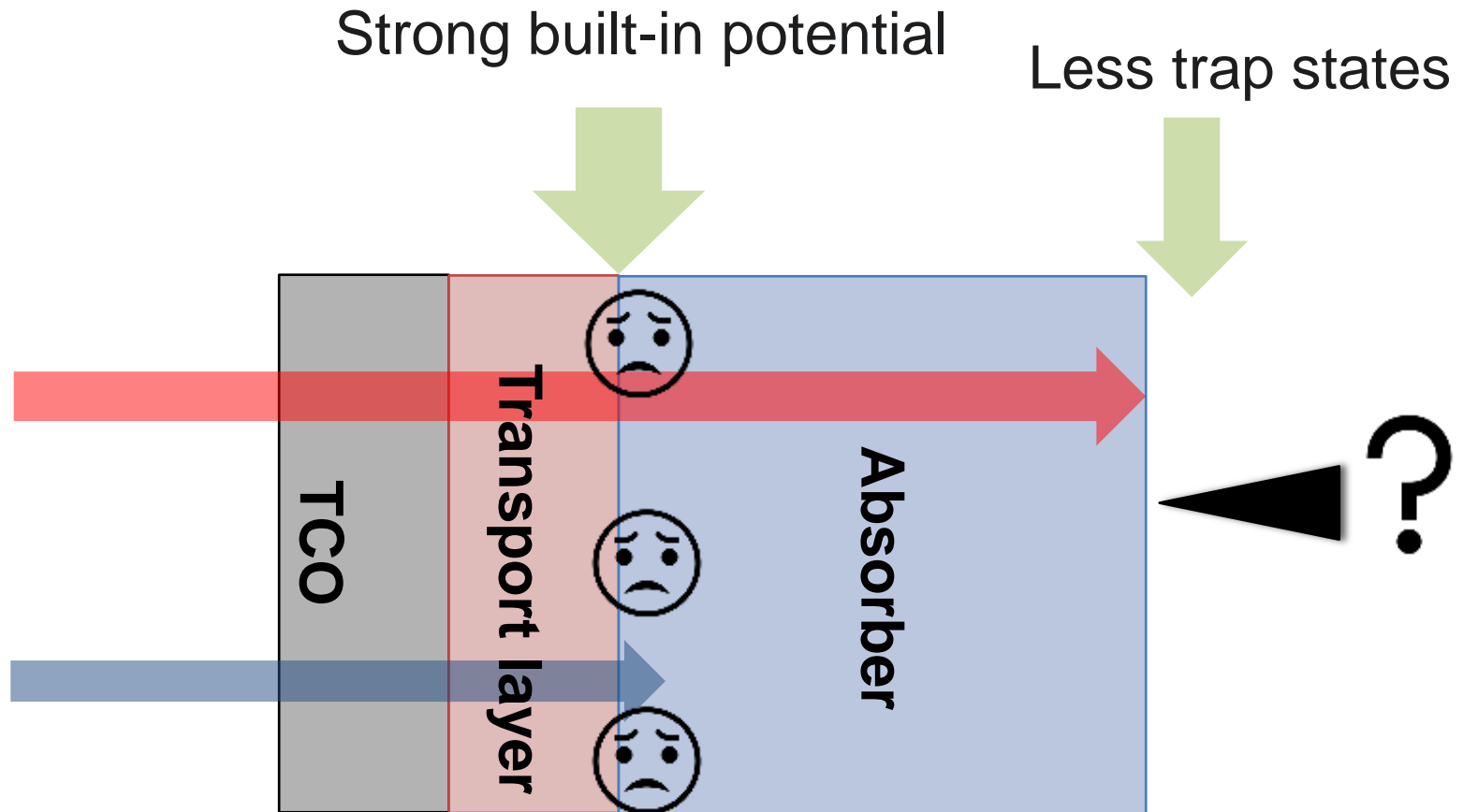
SPV can be expressed by the density of photogenerated charge carriers ($\Delta n = \Delta p$) and the density of minority charge carriers in thermal equilibrium

Top surface depleted by surface defects? Where is pn junction? What is bandgap?

What is diffusion length?

Lecture by Thoas Dittrich, HZB, 2010

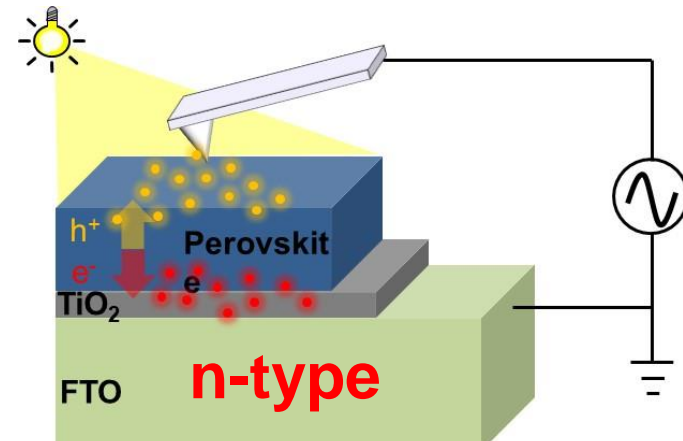
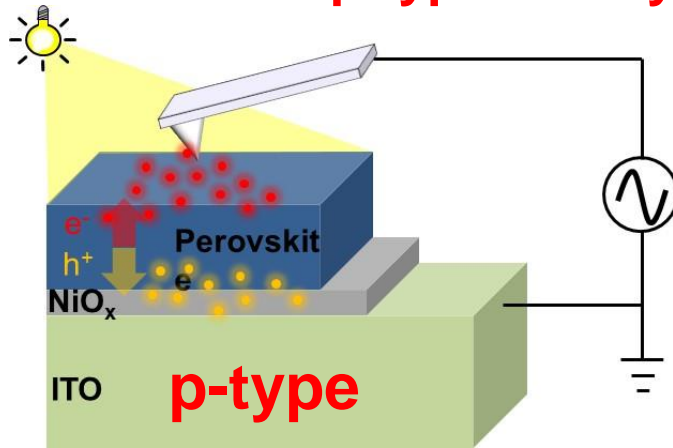
SURFACE PHOTOVOLTAGE



Intensity and wavelength dependent KPFM

SURFACE PHOTOVOLTAGE

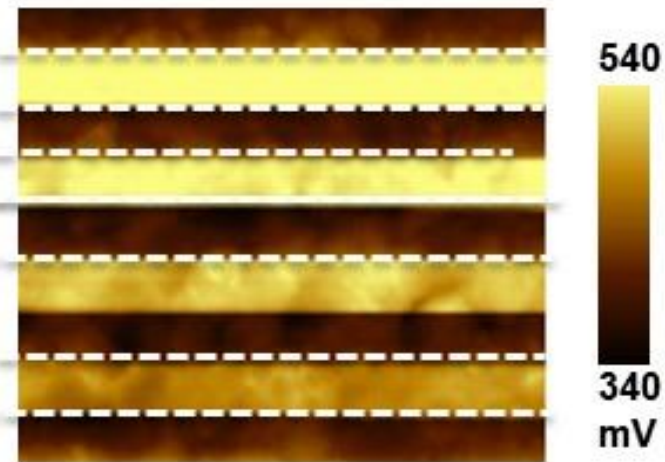
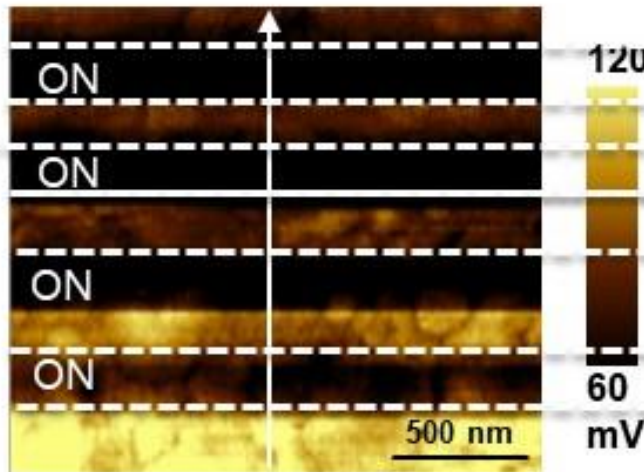
p-type vs n-type transport layer



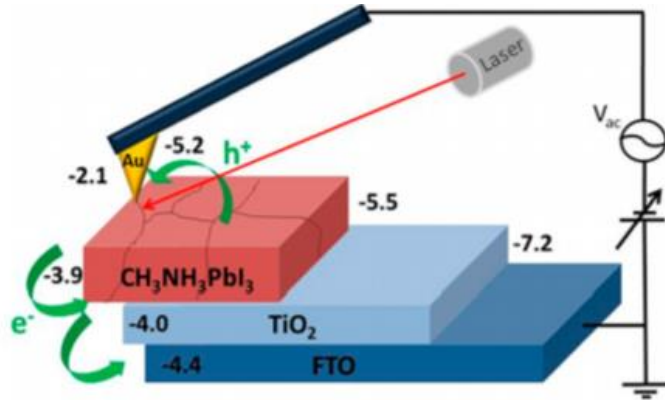
NiO_x

c-TiO_2

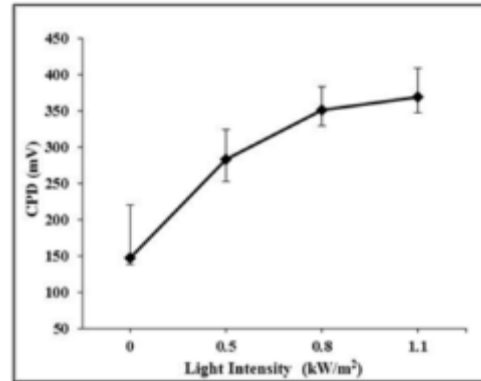
Every 40s



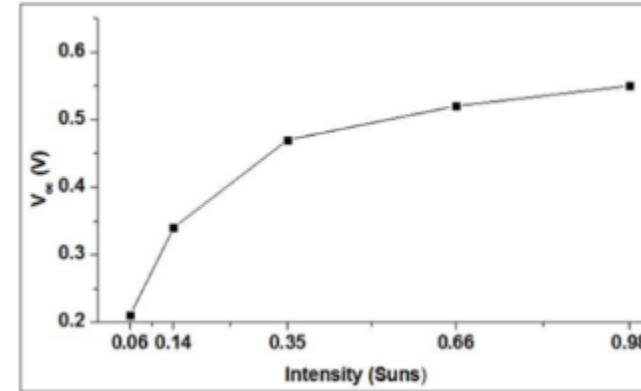
SURFACE PHOTOVOLTAGE



CPD vs. Light Intensity



V_{oc} vs. Intensity



J. Yun et al. The journal of physical chemistry letters 6 (5), 875-880

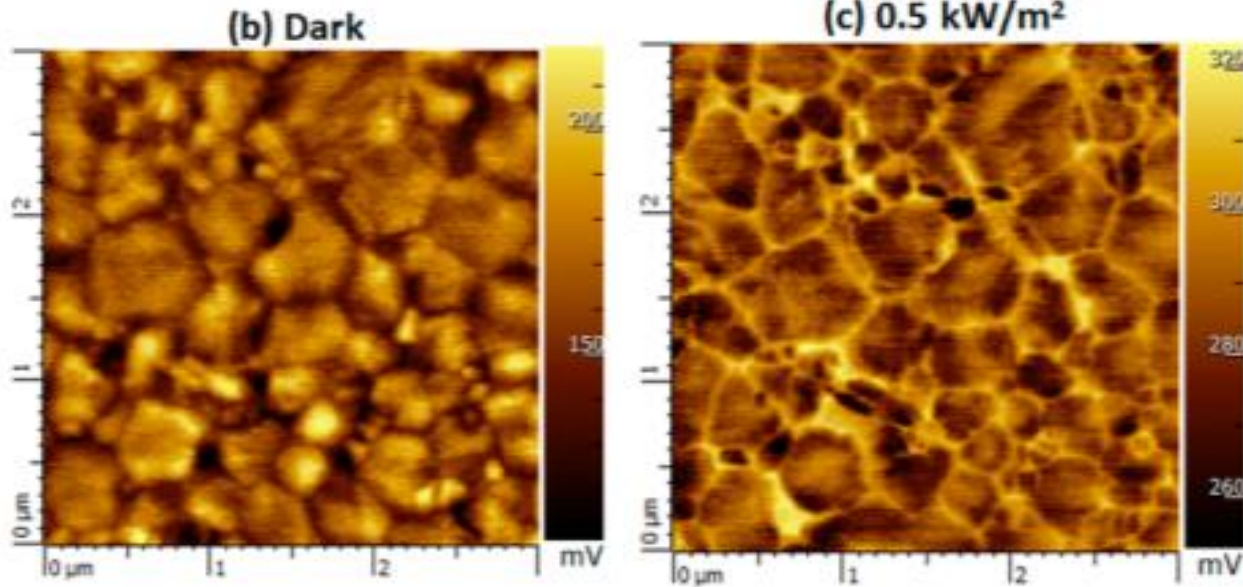
Sub-linear behavior of contact potential difference and open-circuit voltage

Our obtained CPD can be correlated with the open circuit potential under illumination

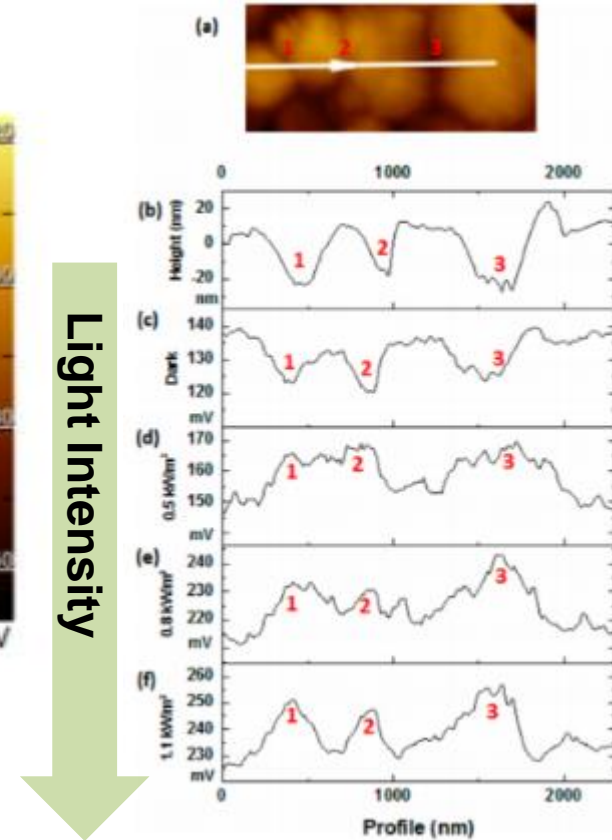
GRAIN BOUNDARIES IN HALIDE PEROVSKITES

CPD in Dark

CPD in light

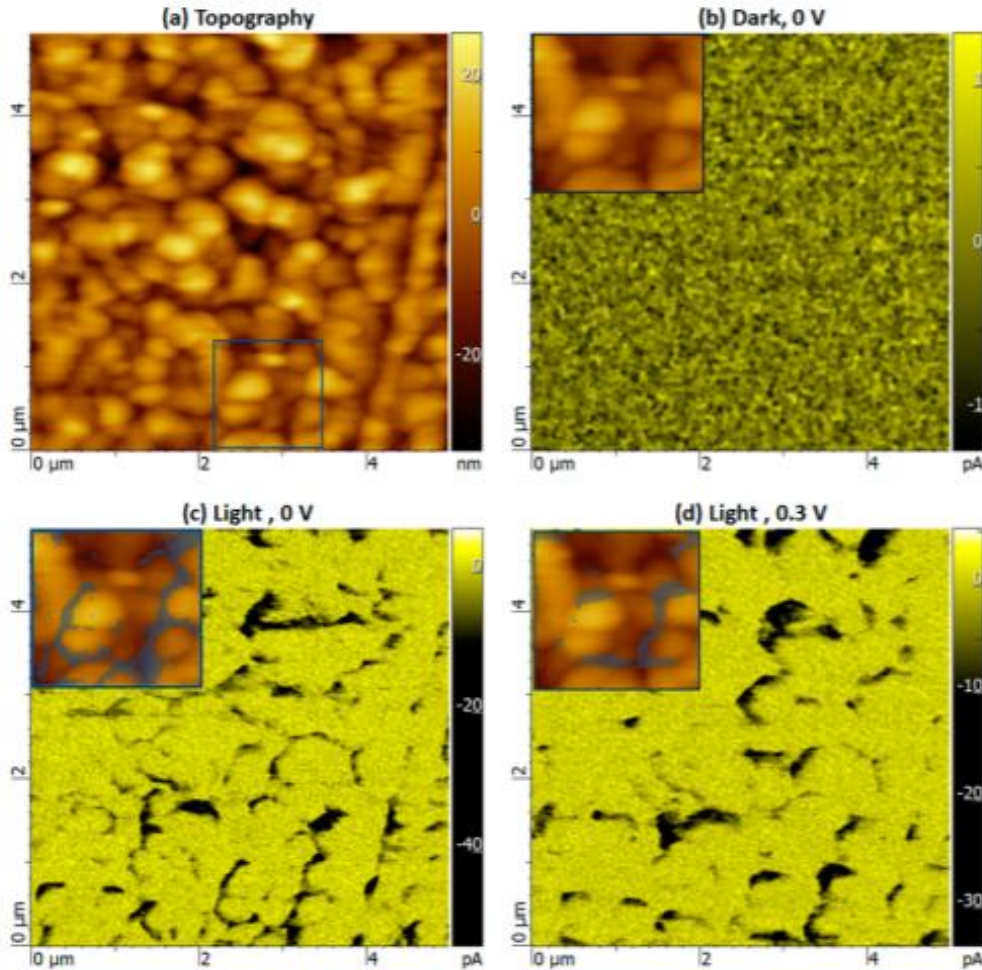


Grain boundaries show higher CPD compare to grain interiors



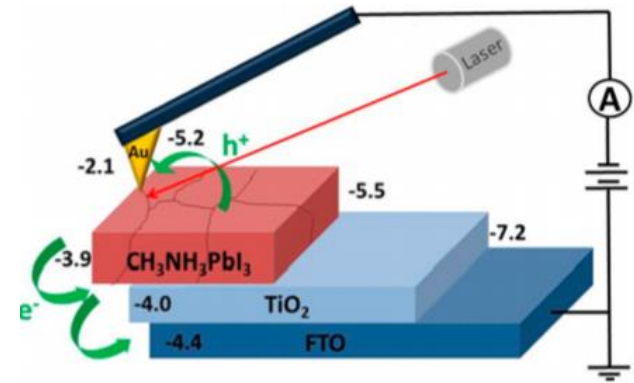
J.Yun et al. The journal of physical chemistry letters 6 (5), 875-880

PHOTOCURRENT MAPPING

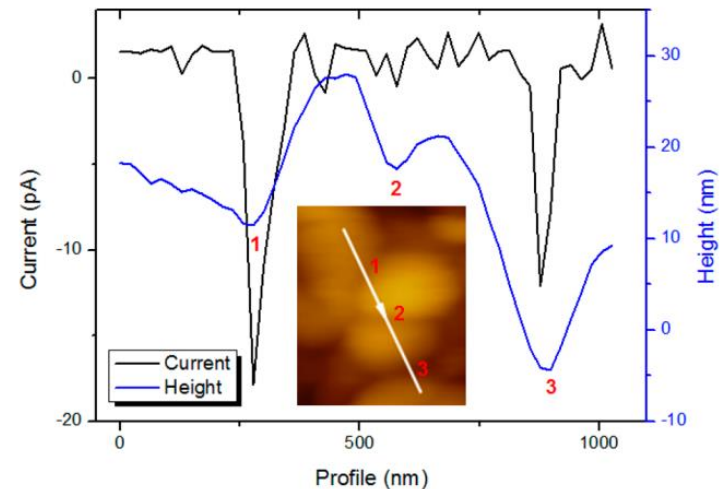


J. Yun et al. The journal of physical chemistry letters 6 (5), 875-880

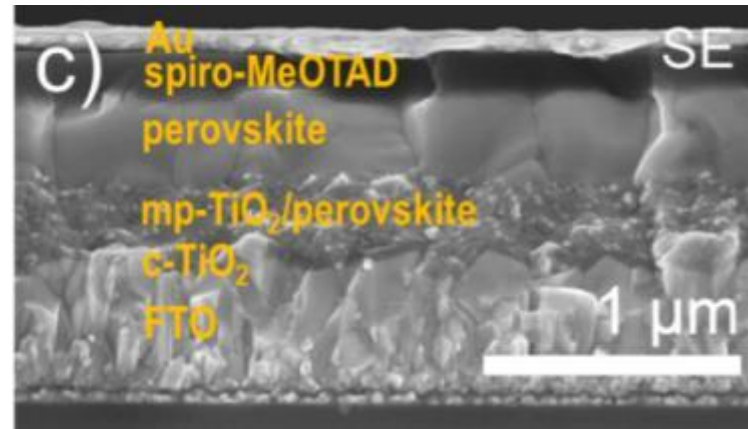
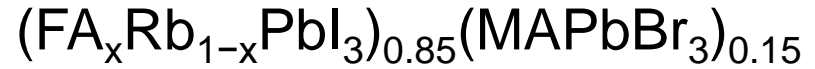
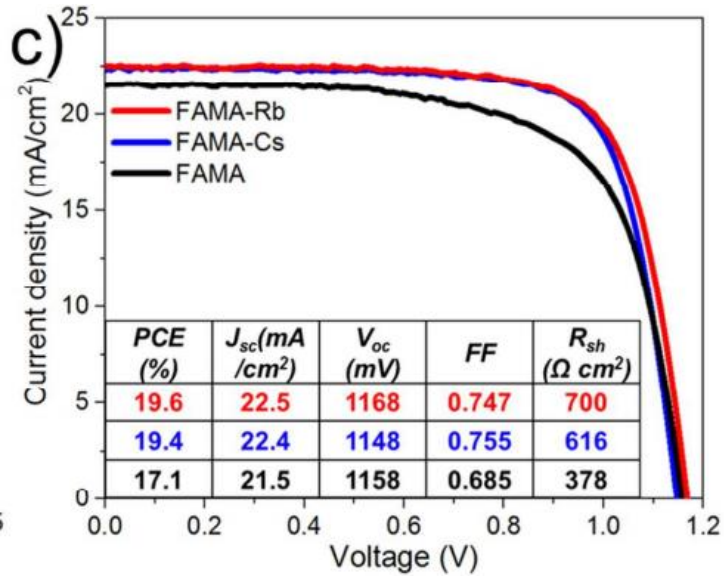
Higher photocurrent at GBs



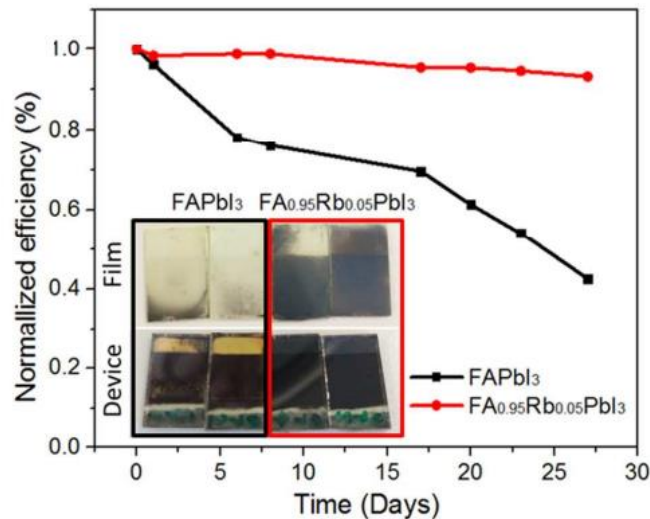
(b) c-AFM Setup



INORGANIC CATION INCORPORATED PEROVSKITES

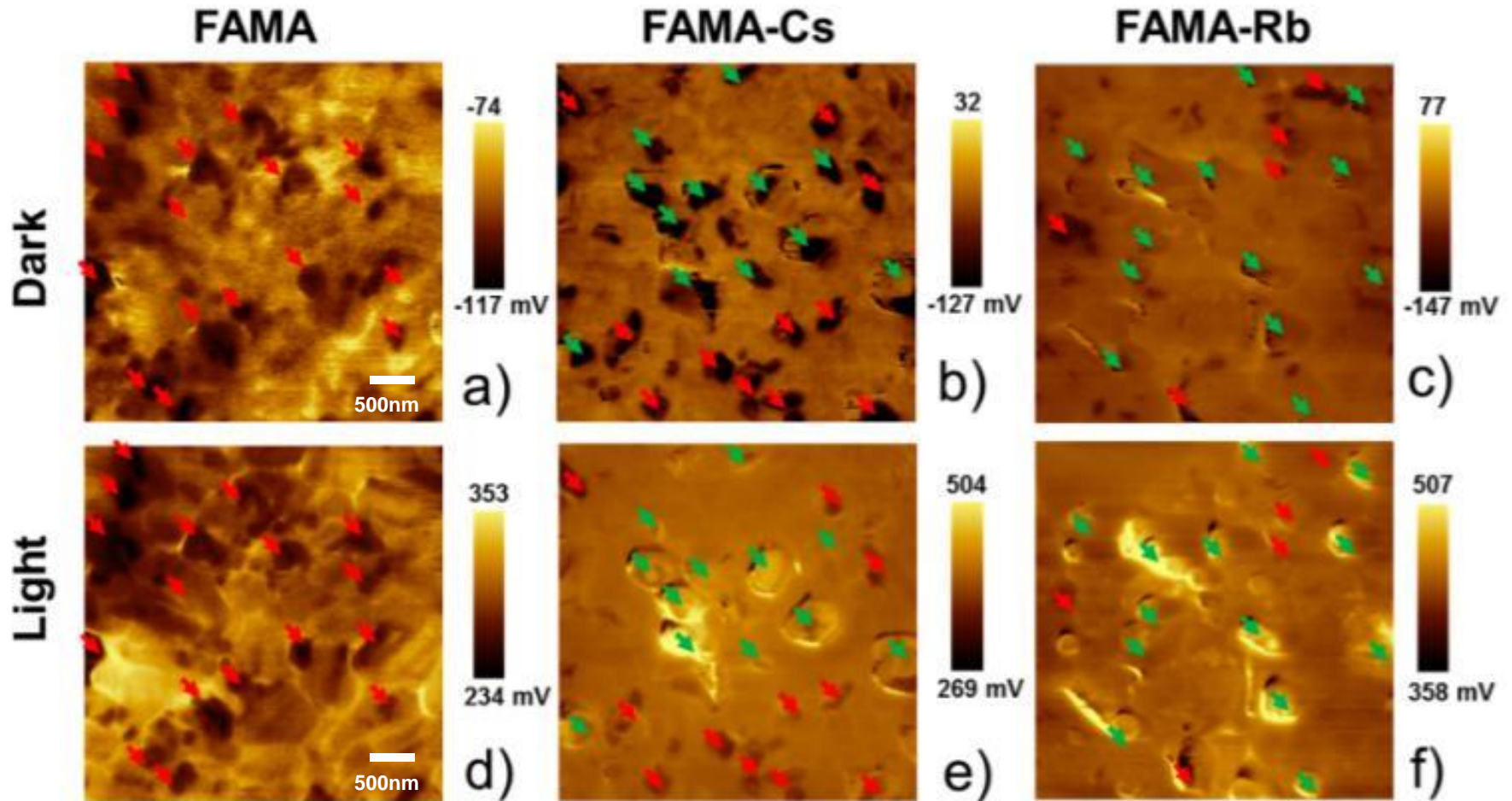


ACS Energy Letters 2 (2), 438-444



Incorporation of Rb improved efficiency and stability

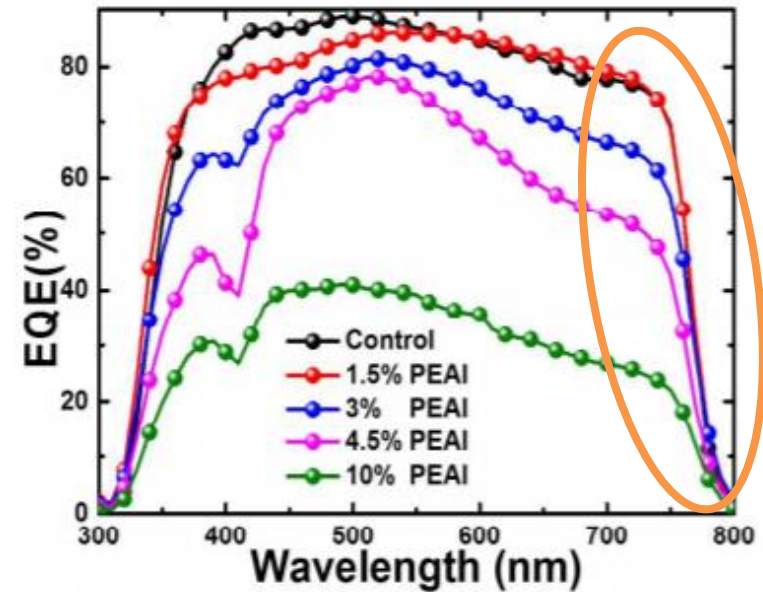
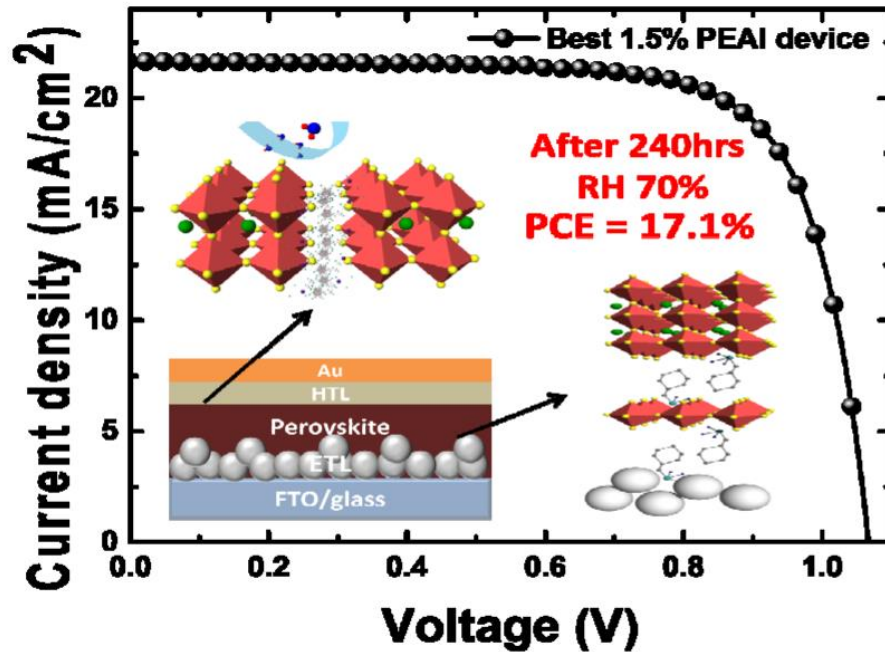
INORGANIC CATION INCORPORATED PEROVSKITES



ACS Energy Letters 2 (2), 438-444

Cs and Rb forms nanoclusters and have higher SPV!!

LONG-CHAINED CATION MIXED PEROVSKITES

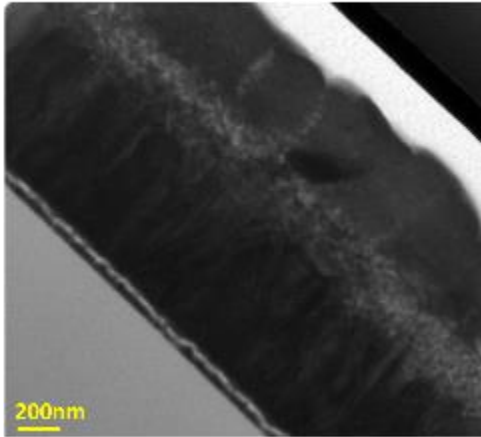


	PEAI	J _{sc}	V _{oc}	FF	PCE
After 1200 hrs.	Control	-64%	-1%	-15%	-71%
	1.5% PEAI	-13%	+7%	-10%	-17%
	3.0% PEAI	1%	-3%	-13%	-15%
	4.5% PEAI	-8%	-9%	-22%	-15%
	10% PEAI	+25%	-1%	18%	52%

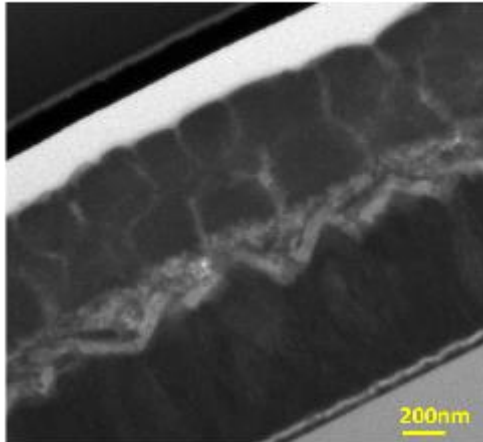
ACS Energy Letters 3 (3), 647-654

LONG-CHAINED CATION MIXED PEROVSKITES

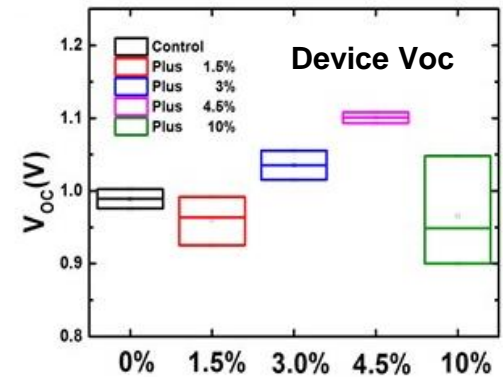
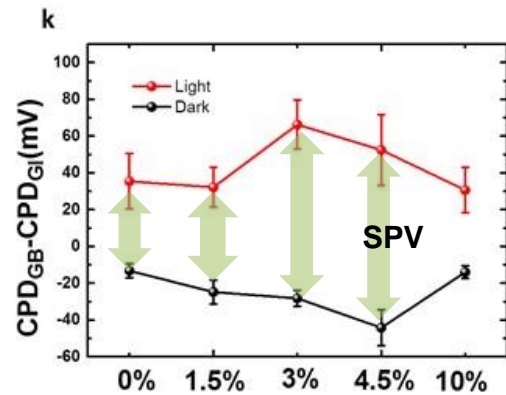
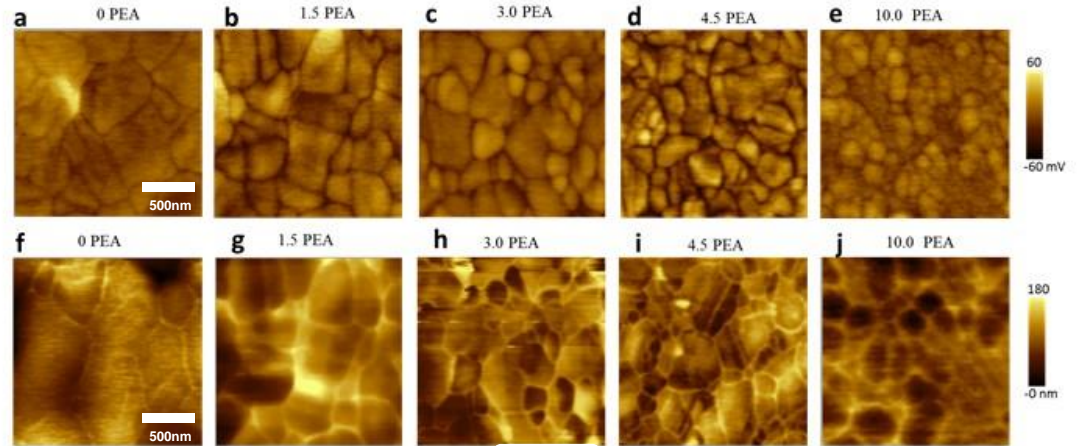
a Reference



b 4.5%PEA



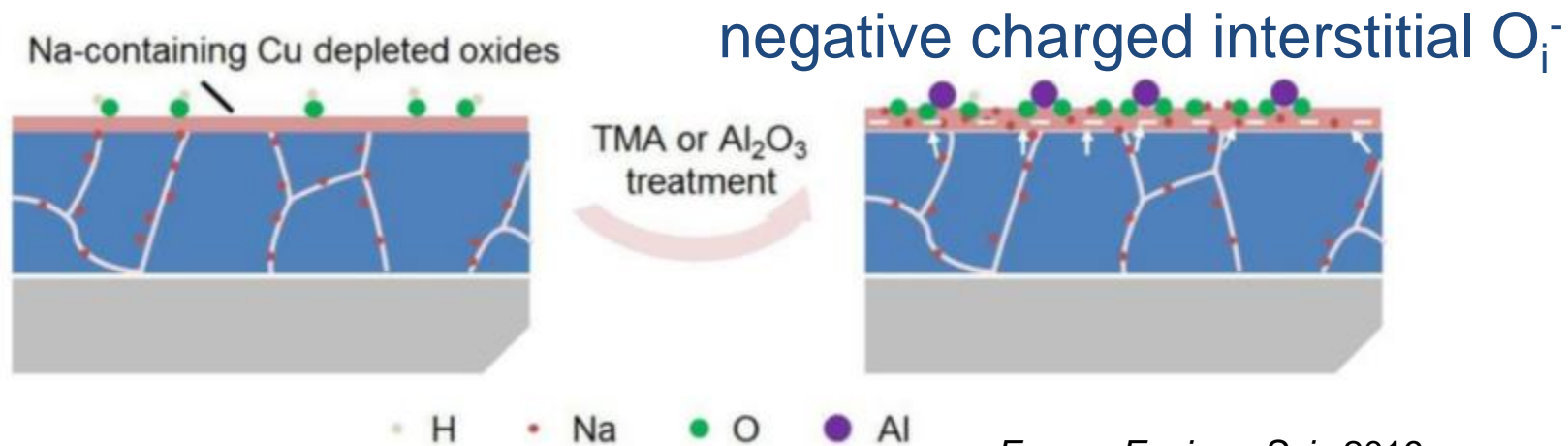
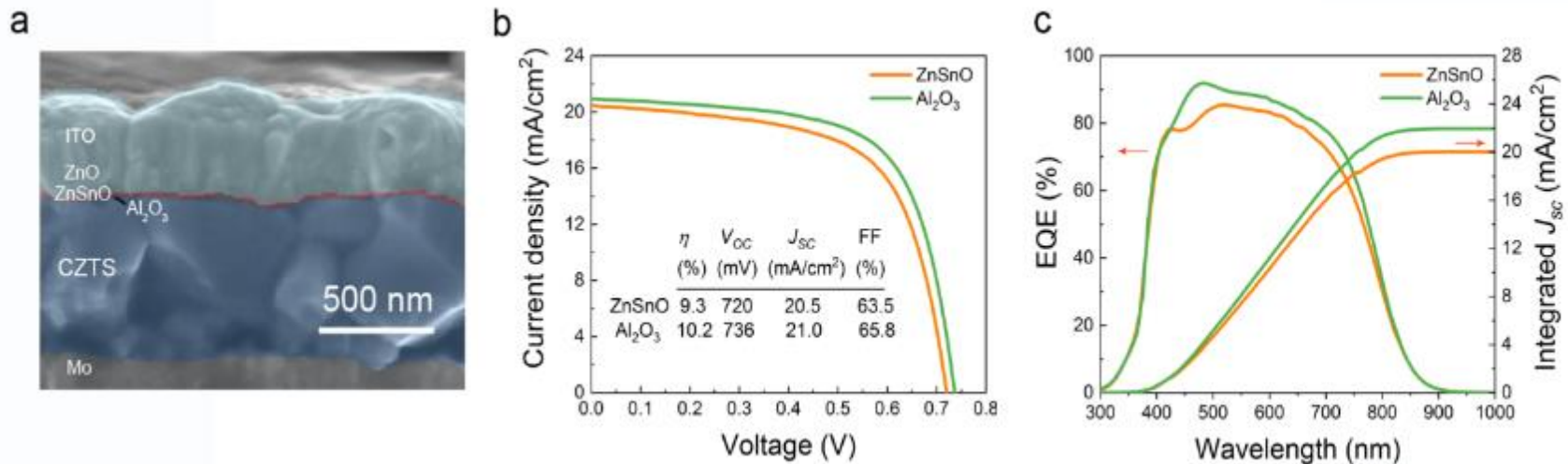
decrease in grain size →



ACS Energy Letters 3 (3), 647-654

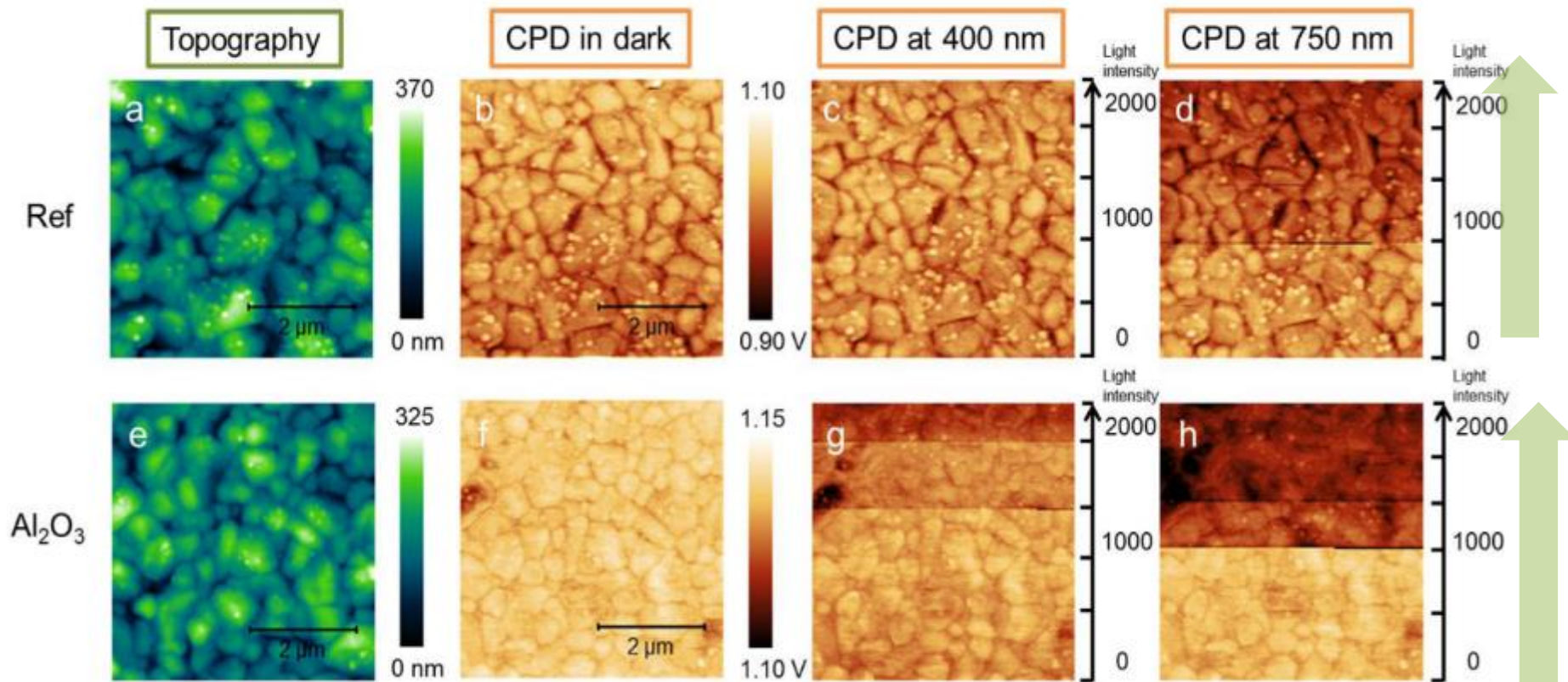
Voc↑ with grain size ↓ Enlarged bandgap at the GBs?

ALUMINA PASSIVATED CZTS SOLAR CELLS



Energy Environ. Sci., 2019

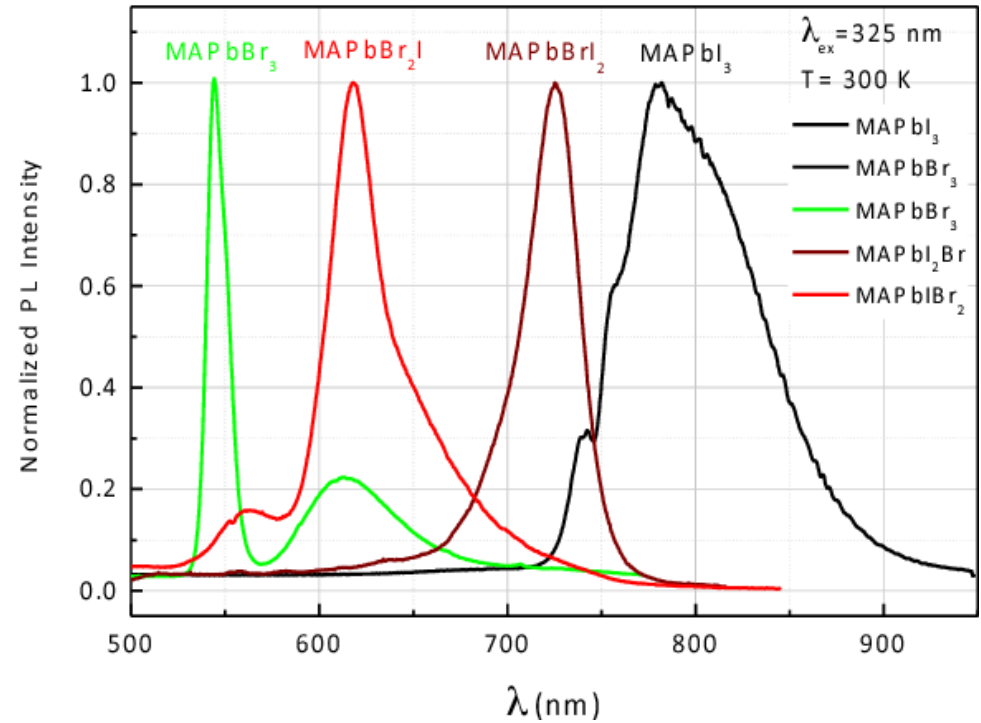
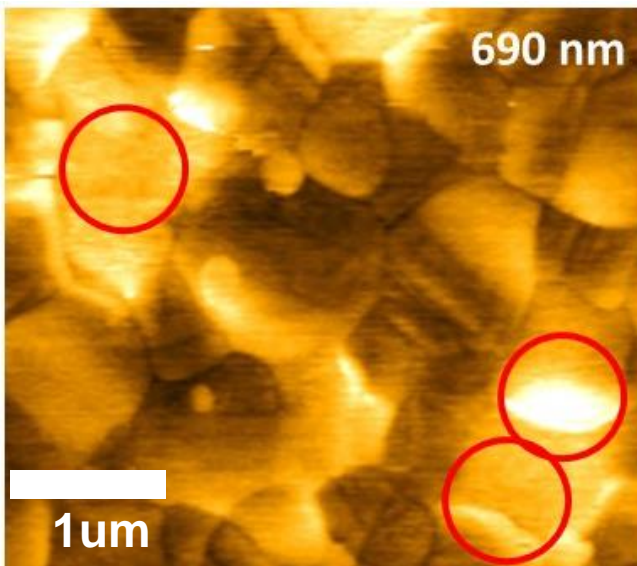
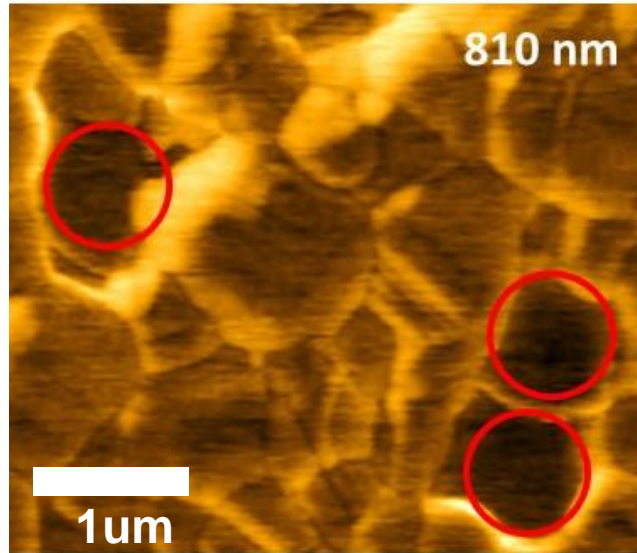
Several nm thick Al₂O₃ layer with trimethylaluminum (TMA) precursor enabled over 10% efficiency!



Energy Environ. Sci., 2019

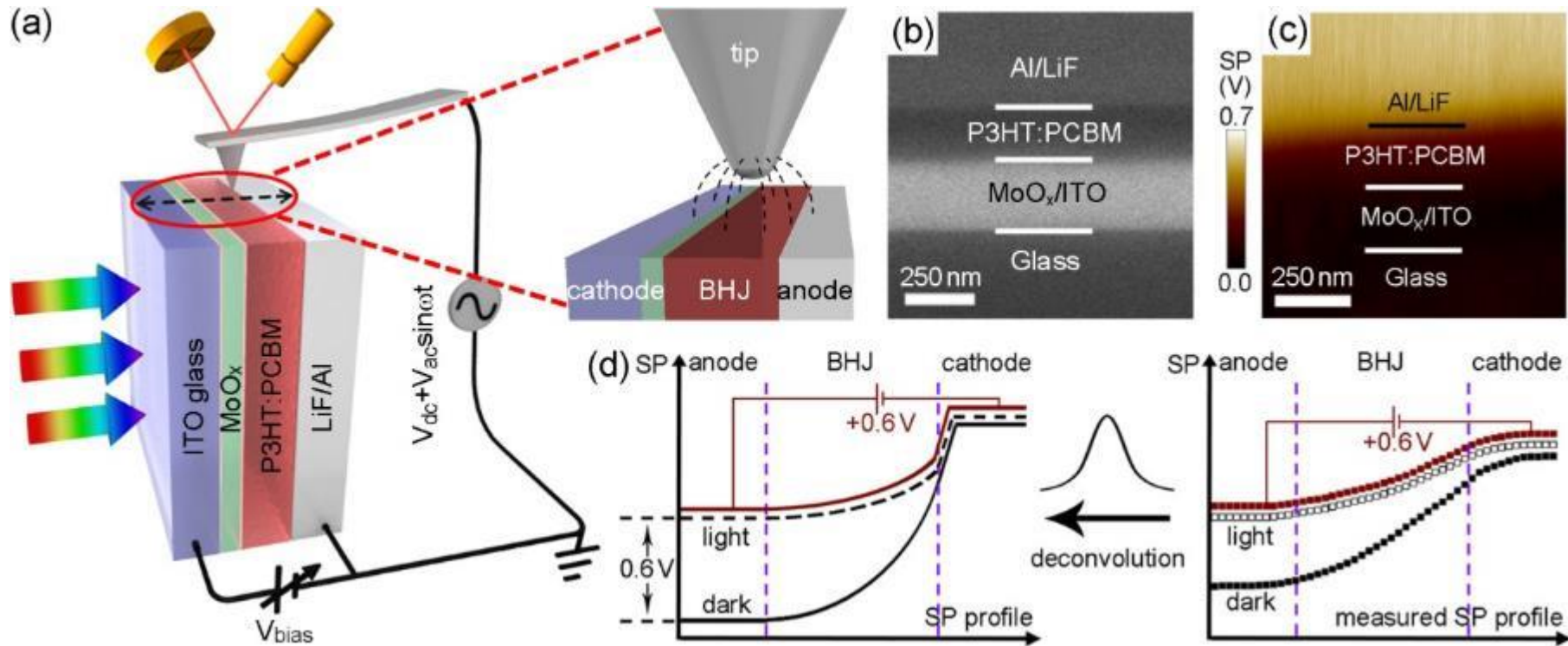
Higher response of CPD at both wavelengths when Al₂O₃ is deposited on top of CZTS

CPD UNDER ILLUMINATION



**Grain to grain band gap difference
from halide segregation**

CROSS-SECTION KPFM



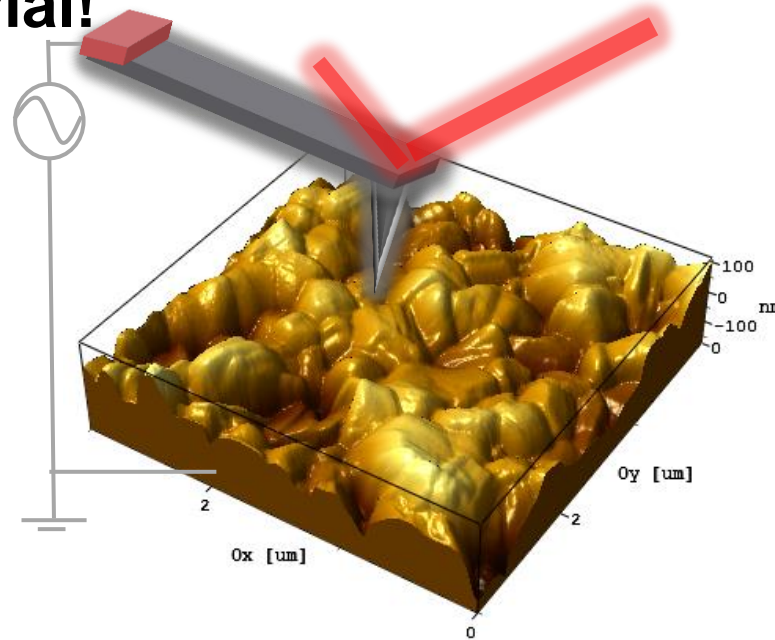
Nature communications 6 (2015): 7745.

pn junction profile, charge transport properties at each

interface, and band alignment

SUMMARY

Allows 3D nanoscale mapping of your material!



Work function distribution, ion migration, charge transport, surface photovoltage, pn junction properties, and many more!

WHERE IS AFM?

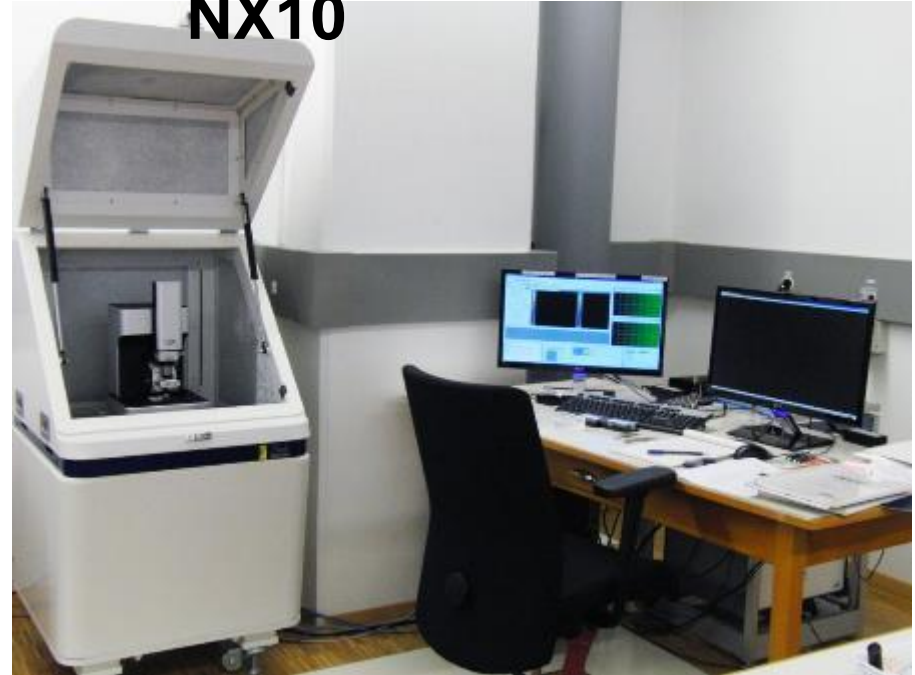
**School of Materials Science
Several AFMs**



Prof. Jan Seidel

**Humidity control, different
environments, temperature
control,
tunable laser, liquid**

**SPREE- Park System
NX10**



**To be installed soon!
KPFM with LED lights, conductive AFM
local**

IV curve, EFM, PFM, Phase imaging

FAQS

1. How long does it take to measure? For instances, 5 x 5 μm^2 ?
2. How easy is it obtain a high quality CPD image?
3. What type of probe to use?
4. What sample roughness is allowed?

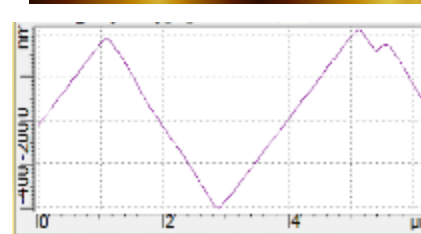
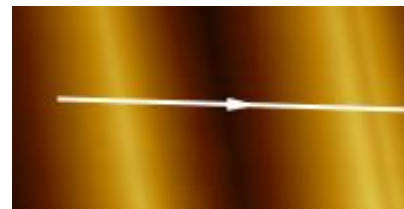
PT-IR COATED PROBES:

- ▶ ANSCM series probes are silicon probes coated with Pt-Ir on both sides for EFM applications.
- ▶ Available as ANSCM-PC, ANSCM-PT and ANSCM-PA probes for Contact, Force modulation and Tapping™/Non-contact EFM applications, respectively.
- ▶ ACCESS (tip view) probes coated with Pt-Ir (ACCESS-EFM) for contact/force modulation mode EFM applications.



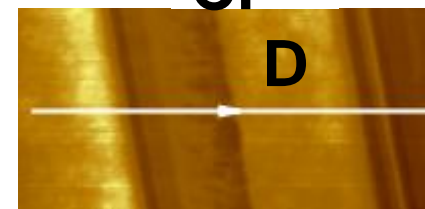
Parameter	ANSCM-PC	ANSCM-PT	ANSCM-PA	ANSCM-PAS	ACCESS-EFM
k (N/m)	0.2	3	40	40	2.7
f (kHz)	12	60	300	300	60
Length	450	225	125	125	245
Width (μm)	40	40	30	30	02
Thickness (μm)	2.5	2.5	4.5	4.5	2.8
Tip ROC (nm)	30	30	30	55	30
PtIr thickness (nm)	20±5	20±5	20±5	50±5	20±5

Height



CP

D





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